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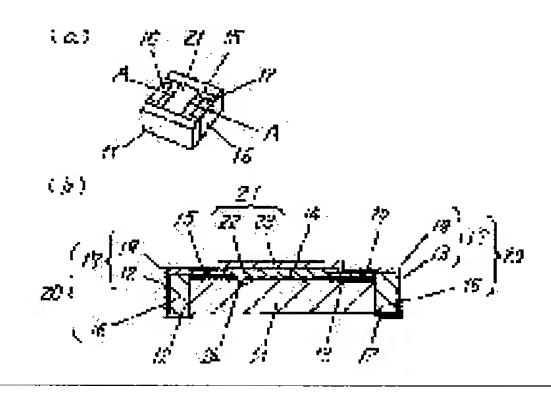
# (54) RESISTOR AND MANUFACTURING METHOD THEREFOR

(57) Abstract:

PROBLEM TO BE SOLVED: To provide a resistor capable of restraining cutting cost of a substrate, and its manufacturing method.

SOLUTION: This resistor consists of a substrate 11, a resistance layer 14 formed on an upper surface of the substrate 11, and a pair of upper surface electrode layers 15 arranged in both end portions of an upper surface of the resistance layer 14. The substrate 11 is composed of a resin based material.

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### **CLAIMS**

# [Claim(s)]

[Claim 1] It is the resistor which has a substrate, the resistive layer prepared in the top face of said substrate, and the top-face electrode layer of the pair prepared in the both ends of the top face of said resistive layer, and is characterized by said substrate consisting of an ingredient of a resin system.

[Claim 2] The resistor according to claim 1 characterized by forming a resistive layer in the top face of the substrate layer which consists of an oxide in which it was prepared on the top face of a substrate.

[Claim 3] The resistor according to claim 1 characterized by a substrate consisting of a liquid crystal polymer.

[Claim 4] The resistor according to claim 1 characterized by forming the external electrode layer which consists of a plating layer formed in the front face of the end-face electrode layer of the pair prepared in the end face of said substrate so that it might connect with the top-face electrode layer of a pair electrically, and said end-face electrode layer in the notching section of the pair in which it was prepared to the both ends of said substrate.

[Claim 5] The resistor according to claim 4 characterized by constituting an end-face electrode layer from an ingredient which consists of metal powder and resin.

[Claim 6] The resistor according to claim 4 characterized by preparing the top face of an external electrode layer above the top face of a protective coat.

[Claim 7] The resistor according to claim 4 characterized by making it not prepare an external electrode layer in the rear face of a substrate.

[Claim 8] The resistor according to claim 4 characterized by preparing an external electrode layer in the top face of a top-face electrode layer.

[Claim 9] The resistor according to claim 1 characterized by consisting of the 1st protective layer which the protective coat prepared so that a resistive layer might be covered at least becomes from an oxide, and the 2nd protective layer which consists of resin formed in the top face of said 1st protective layer.

[Claim 10] A substrate, two or more resistive layers prepared in the top face of said substrate, and two or more pairs of top—face electrode layers prepared in the both ends of each top face of two or more of said resistive layers, Two or more external electrode layers which consist of a plating layer formed in the front face of said two or more pairs of end—face electrode layers prepared in the end face of said substrate so that more than one might connect with a pair of top—face electrode layer electrically, and said end—face electrode layer, Said substrate is a resistor characterized by forming a crevice in the part which consists of an ingredient of a resin system and is located between said external electrode layers in the end face of said substrate.

[Claim 11] The process which prepares the substrate layer which becomes the substrate which consists of an ingredient of a resin system from an oxide, So that it may connect with the process which prepares a resistive layer in the top face of said substrate layer, the process which prepares the top-face electrode layer of a pair in the both ends of the top face of said resistive layer, and the top-face electrode layer of said pair electrically The manufacture approach of the resistor characterized by having the process which prepares the end-face electrode layer of the pair formed in the end face of said substrate, the process which prepares a plating layer in the front face of the end-face electrode layer of said pair, and forms an external electrode layer, and the process which prepares a protective coat so that said resistive layer may be covered at least.

[Claim 12] The manufacture approach of the resistor according to claim 11 characterized by making it form by stiffening the mixed paste which consists an end-face electrode layer of metal powder and resin.

[Claim 13] The manufacture approach of the resistor according to claim 11 characterized by carrying out pattern NINGU with a FOTORISO method of construction at a predetermined configuration, respectively after forming a top-face electrode layer and a resistive layer by the spatter.

[Claim 14] A substrate layer and a protective coat are the manufacture approach of the resistor according to claim 11 characterized by what was formed of the spatter.

[Claim 15] The process which prepares a substrate layer in the substrate which consists of an ingredient of a resin system, and the process which prepares two or more resistive layers in the top face of said substrate layer, So that it may connect with the process which prepares two or more pairs of top-face electrode layers in the both ends of the top face of two or more of said resistive layers, and said two or more pairs of top-face electrode layers

electrically The process which prepares a plating layer in the front face of two or more pairs of end-face electrode layers formed in the end face of said substrate, and said end-face electrode layer, and forms an external electrode layer, The manufacture approach of the resistor characterized by forming a crevice in the part which is equipped with the process which prepares a protective coat so that said two or more resistive layers may be covered at least, and is located between said external electrode layers in the end face of said substrate.

[Claim 16] The manufacture approach of the resistor according to claim 11 or 15 characterized by establishing the fluting and transverse groove for division in a substrate so that the field equivalent to one resistor may be divided continuously, after preparing a protective coat at least, dividing said substrate along the fluting and transverse groove for said division, and obtaining two or more resistors.

[Claim 17] The manufacture approach of the resistor according to claim 16 characterized by forming the fluting and transverse groove for division with laser.

[Claim 18] The manufacture approach of the resistor according to claim 16 characterized by having prepared the through tube so that the part used as the fluting of a substrate might be straddled and a transverse groove might not be straddled, connecting said conductor to a top-face electrode layer electrically, and preparing an end-face electrode layer while making said through tube fill up with a conductor.

[Claim 19] The manufacture approach of the resistor according to claim 16 characterized by having prepared the through tube so that the part used as the fluting of a substrate might be straddled and a transverse groove might not be straddled, and forming an end-face electrode layer in said through tube by the spatter.

[Claim 20] The manufacture approach of the resistor according to claim 16 characterized by forming an end-face electrode layer in the fluting or transverse groove for division by the spatter.

[Claim 21] The manufacture approach of the resistor according to claim 16 characterized by dividing a substrate as the fluting and transverse groove for division are established in a substrate and said sheet bridging is made to separate from a substrate after that after sticking a sheet bridging on a substrate.

[Claim 22] The manufacture approach of the resistor according to claim 21 characterized by using the thing containing the adhesives which have an ultraviolet curing property as a sheet bridging.

[Claim 23] The process into which a sheet bridging is made to separate from a substrate is the manufacture approach of the resistor according to claim 22 characterized by carrying out by irradiating ultraviolet rays.

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#### DETAILED DESCRIPTION

# [Detailed Description of the Invention]

# [0001]

[Field of the Invention] This invention relates to the resistor used for various electronic equipment or the multiple-string chip resistor by which pattern formation was carried out minutely, and its manufacture approach.

## [0002]

[Description of the Prior Art] In order to raise the packaging density to a printed circuit board with the miniaturization of electronic equipment in recent years, the demand of multiple-string-izing from which a miniaturization and two or more independent components are one unit has been increasing to electronic parts, such as a resistor used for electronic equipment.

[0003] What was indicated by the microfilter of JP,4-38001,U is known as a conventional resistor.

[0004] In addition, the multiple-string chip resistor with which the resistive layer which the plurality which is one of resistors became independent of is one unit is described as a resistor here.

[0005] Hereafter, a conventional resistor and its conventional manufacture approach are explained, referring to a drawing.

[0006] <u>Drawing 18</u> (a) is the perspective view of the conventional resistor, and <u>drawing 18</u> (b) is this E-E line sectional view.

[0007] In <u>drawing 18</u>, 1 is an insulating substrate which consists of an alumina. 2 is two pairs of top-face electrode layers prepared in the both ends of the top face of an insulating substrate 1. 3 is two resistive layers prepared so that a part might lap with two pairs of top-face electrode layers 2. At this time, two resistive layers 3 have been independent. 4 is the protective layer prepared so that the two whole resistive layer 3 might be covered. 5a is two pairs of side-face electrode layers prepared in the side face of an insulating substrate 1. 5b is a plating layer which consists of nickel

prepared in the front face of two pairs of top-face electrode layers 2, and 2 pairs of side-faces electrode layer 5a, and solder plating.

[0008] About the conventional resistor constituted as mentioned above, the manufacture approach is explained below, referring to a drawing.

[0009] <u>Drawing 19</u> and <u>drawing 20</u> are process drawings showing the manufacture approach of the conventional resistor.

[0010] First, insulating-substrate 8a of the shape of a sheet in the case of manufacturing the conventional resistor to drawing 19 (a) is shown. Division slot 10b of the division slot 10a and the longitudinal direction of a through hole 9 and a lengthwise direction is formed in this insulating-substrate 8a. [0011] Next, as shown in drawing 19 (b), printing formation of two or more resistive layers 3 is carried out so that printing formation of two or more pairs of top-face electrode layers 2 may be carried out and it may lap with the top face of sheet-like insulating-substrate 8a further at a part of each of a pair of top-face electrode layer 2.

[0012] Next, after carrying out printing formation of two or more protective layers 4 so that two or more whole resistive layers 3 may be covered as shown in <u>drawing 20</u> (a), it divides along with lateral division slot 10b (it illustrates to <u>drawing 18</u>), and divides into strip—of—paper—like insulating—substrate 8b.

[0013] Next, as shown in <u>drawing 20</u> (b), application formation of the side-face electrode layer 5a is carried out at the lateral portion of strip-of-paper-like insulating-substrate 8b.

[0014] Then, strip-of-paper-like insulating-substrate 8b is divided along with division slot 10a of a lengthwise direction, and a piece of individual-like insulating substrate (not shown) is obtained.

[0015] Finally, as shown in <u>drawing 18</u> (a), after performing nickel plating to the front face of the top-face electrode layer 2 and side-face electrode layer 5a, by performing solder plating, plating layer 5b was formed and the conventional resistor was manufactured.

[0016] Moreover, the resistor of the very small multiple-string form which built two elements in the die-length [ of 0.6mm ] x width-of-face [ of 0.8mm ] x thickness of 0.35mm in recent years has also come to be manufactured by miniaturizing said resistor very much.

[0017]

[Problem(s) to be Solved by the Invention] Since what calcinated porcelain, such as an alumina, as a substrate 1 was used for the above-mentioned conventional resistor, dimension variation had produced it in the substrate by the presentation variation of a substrate, or the temperature variation at the time of baking (this dimension variation amounts to about 0.5mm in the substrate of 100mm of about 100mmx abbreviation).

[0018] When a resistor was manufactured using a substrate with this

dimension variation, many masks used for screen-stencil were prepared, it will be necessary to exchange masks according to the dimension variation of a substrate, and the process was complicated very much.

[0019] Namely, since a formation location will shift and it will become a defect, if the mask used for the screen-stencil for forming the top-face electrode layer 2, a resistive layer 3, a protective layer 4, etc. to a substrate with dimension variation shifts, it is because the mask used for screen-stencil of the top-face electrode layer 2 which classifies a substrate with dimension variation into a fine dimension rank, and is equivalent to each dimension rank, a resistive layer 3, a protective layer 4, etc. is needed (a dimension rank — a lengthwise direction —) When classifying according to 0.05mm unit of each longitudinal direction, about 600 or more ranks needed to be dimension classified. Moreover, since especially a multiple-string chip resistor has the resistive layer which plurality became independent of in one unit, a top-face electrode layer, a resistive layer, and a protective layer serve as a very detailed pattern configuration, and this poses a very big problem.

[0020] Furthermore, although the need of classifying a substrate into a dimension rank will be lost if a substrate is cut after screen—stencil of a top—face electrode layer, a resistive layer, a protective layer, etc. in order to cancel the complicatedness of the above—mentioned process If it carries out using the cutting edge containing a diamond so that the silicon wafer of a semi—conductor may be cut for this cutting, since the alumina is harder than the silicon wafer of a semi—conductor, Wear of the cutting edge for dividing had very much the technical problem that cutting cost became great, in early, consequently this approach.

[0021] This invention solves the above-mentioned conventional technical problem, and aims at offering the resistor which can hold down the cutting cost of a substrate, and its manufacture approach.

[0022]

[Means for Solving the Problem] In order to attain the above-mentioned purpose, the resistor of this invention has a substrate, the resistive layer prepared in the top face of said substrate, and the top-face electrode layer of the pair prepared in the both ends of the top face of said resistive layer, it is characterized by said substrate consisting of an ingredient of a resin system, and according to this configuration, the effectiveness that the cutting cost of a substrate can be held down is acquired.

[0023]

[Embodiment of the Invention] It is what is characterized by for invention of this invention according to claim 1 having a substrate, the resistive layer prepared in the top face of said substrate, and the top-face electrode layer of the pair prepared in the both ends of the top face of said resistive layer,

and said substrate consisting of an ingredient of a resin system. Since the substrate which consists of an ingredient of a resin system softer than an alumina was used according to this configuration, wear of the cutting edge for substrate cutting can be suppressed, and this has an operation that the cutting cost of a substrate can be held down.

[0024] It is what is characterized by invention according to claim 2 forming a resistive layer in the top face of the substrate layer which consists of an oxide in which it was prepared on the top face of a substrate. Since the substrate layer which consists of an oxide was formed in the substrate top face which consists of an ingredient of the resin system which is generally hygroscopic according to this configuration, invasion to the substrate of moisture can be decreased by the substrate layer which consists of an oxide, and this has an operation that the moisture resistance of a substrate improves.

[0025] Since invention according to claim 3 is characterized by a substrate consisting of a liquid crystal polymer, and the coefficient of thermal expansion of a substrate can choose it easily according to this configuration, it can adjust relation with the coefficient of thermal expansion of a resistive layer or a printed circuit board, and, thereby, has an operation that the curvature of the substrate at the time of use by the difference in a coefficient of thermal expansion etc. can be prevented.

[0026] Invention according to claim 4 the external electrode layer which consists of a plating layer formed in the front face of the end-face electrode layer of the pair prepared in the end face of said substrate so that it might connect with the top-face electrode layer of a pair electrically, and said end-face electrode layer It is what is characterized by forming in the notching section of the pair prepared in the both ends of a substrate. According to this configuration, it has an operation that the resistor by which only the part in which an end-face electrode layer does not project from a substrate included the end-face electrode layer is made into a miniaturization, rather than what prepared the end-face electrode layer in the substrate without the notching section.

[0027] Since invention according to claim 5 is characterized by constituting an end-face electrode layer from an ingredient which consists of metal powder and resin, and it can calcinate an end-face electrode layer at the low temperature of 130 degrees C – 240 degrees C according to this configuration, it can suppress the effect of the heat to a resistive layer, and, thereby, has an operation that the resistance value change under production can be made small.

[0028] Invention according to claim 6 is characterized by preparing the top face of an external electrode layer more nearly up than the top face of a protective coat, and even if it turns the top-face side of a substrate to a

printed circuit board side, in order that the top face of an external electrode may contact a printed circuit board according to this configuration, whichever it turns [ of the vertical side of a substrate ] to a printed circuit board side, it has an operation that mounting becomes possible.

[0029] Invention according to claim 7 is characterized by making it not

[0029] Invention according to claim 7 is characterized by making it not prepare an external electrode layer in the rear face of a substrate, and according to this configuration, since the stability at the time of adsorption improves when the rear face of a substrate is adsorbed by the adsorption pin of an automatic mounting machine, the top—face side of a substrate is turned to a printed circuit board side and it mounts in a printed circuit board, it has an operation that the high rate of mounting is securable.

[0030] It is what is characterized by invention according to claim 8 preparing an external electrode layer in the top face of a top-face electrode layer. Since the touch area of an external electrode layer and a top-face electrode layer becomes large according to this configuration, Even if it receives environmental loads, such as a thermal shock, the increment in contact resistance in the meantime can be suppressed, and thereby, since a resistive layer can make small the rate of the increment of the contact resistance to the resistance of a resistive layer also in low \*\*\*\*\*\*, it has an operation that the rate of a change in resistance can be made low.

[0031] It is what is characterized by invention according to claim 9 consisting of the 1st protective layer which the protective coat prepared so that a resistive layer might be covered at least becomes from an oxide, and the 2nd protective layer which consists of resin formed in the top face of said 1st protective layer. Since a resistive layer is covered by the 1st protective layer which consists of a heat-resistant outstanding oxide, and the 2nd protective layer which consists of resin excellent in moisture resistance according to this configuration, a resistive layer is not influenced of heat or moisture, but, thereby, has an operation that the rate of a change in resistance at the time of use can be made small.

[0032] Two or more resistive layers by which invention according to claim 10 was prepared in the top face of a substrate and said substrate. Two or more pairs of top—face electrode layers prepared in the both ends of each top face of two or more of said resistive layers, Two or more external electrode layers which consist of a plating layer formed in the front face of said two or more pairs of end—face electrode layers prepared in the end face of said substrate so that more than one might connect with a pair of top—face electrode layer electrically, and said end—face electrode layer, It is what is characterized by forming a crevice in the part which it has the protective coat prepared so that said two or more resistive layers might be covered at least, and said substrate consists of an ingredient of a resin system, and is located between said external electrode layers in the end face of said substrate. Since the

substrate which consists of an ingredient of a resin system softer than an alumina was used according to this configuration. In the multiple-string chip resistor which has the resistive layer which plurality became independent of in addition to the ability to suppress wear of the cutting edge for substrate cutting, and hold down the cutting cost of a substrate by this Since the distance in the end face of a substrate is separated between each external electrode layer corresponding to each resistive layer with the crevice, it has an operation that it can prevent that external electrode layers contact and resistive layers connect electrically at the time of formation of an external electrode layer.

[0033] The process which prepares the substrate layer which becomes the substrate with which invention according to claim 11 consists of an ingredient of a resin system from an oxide, So that it may connect with the process which prepares a resistive layer in the top face of said substrate layer, the process which prepares the top-face electrode layer of a pair in the both ends of the top face of said resistive layer, and the top-face electrode layer of said pair electrically The process which prepares the end-face electrode layer of the pair formed in the end face of said substrate, and the process which prepares a plating layer in the front face of the end-face electrode layer of said pair, and forms an external electrode layer, It is what is characterized by having the process which prepares a protective coat so that said resistive layer may be covered at least. Since the substrate which consists of an ingredient of a resin system softer than an alumina was used according to this manufacture approach, wear of the cutting edge for substrate cutting at the time of substrate cutting can be suppressed, and this has an operation that the cutting cost of a substrate can be held down. [0034] It is what is characterized by forming invention according to claim 12 by stiffening the mixed paste which consists an end-face electrode layer of metal powder and resin. According to this manufacture approach, since it can calcinate at the low temperature of 130 degrees C - 240 degrees C of end-face electrode layers, the effect of the heat to a resistive layer can be suppressed, and this has an operation that the resistance value change under production can be made small.

[0035] It is what is characterized by carrying out pattern NINGU of it with a FOTORISO method of construction at a predetermined configuration, respectively after invention according to claim 13 forms a top-face electrode layer and a resistive layer by the spatter. Since a top-face electrode layer and a resistive layer can be formed thinly according to this manufacture approach, Since pattern formation of the resistive layer is carried out with high precision by the FOTORISO process in addition to becoming easy to divide a substrate in the fluting or transverse groove for division, Effective area of a resistive layer can be enlarged, and thereby, even if high power is

impressed, it has an operation that the rate of a change in resistance can be made low.

[0036] Since invention according to claim 14 is characterized by what the substrate layer and the protective coat were formed for of the spatter, and it can form a substrate layer and a protective coat precisely according to this manufacture approach, moisture stops being able to enter easily to a resistive layer, and, thereby, it has an operation that a resistive layer is stabilized.

[0037] The process which prepares a substrate layer in the substrate with which invention according to claim 15 consists of an ingredient of a resin system, So that it may connect with the process which prepares two or more resistive layers in the top face of said substrate layer, the process which prepares two or more pairs of top-face electrode layers in the both ends of the top face of two or more of said resistive layers, and said two or more pairs of top-face electrode layers electrically The process which prepares a plating layer in the front face of two or more pairs of end-face electrode layers formed in the end face of said substrate, and said end-face electrode layer, and forms an external electrode layer, It is what is characterized by forming a crevice in the part which is equipped with the process which prepares a protective coat so that said two or more resistive layers may be covered at least, and is located between said external electrode layers in the end face of said substrate. In order to use the substrate which consists of an ingredient of a resin system softer than an alumina according to this manufacture approach, In the multiple-string chip resistor which has the resistive layer which plurality became independent of in addition to the ability to suppress wear of the cutting edge for substrate cutting, and hold down the cutting cost of a substrate by this In order that the distance in the end face of a substrate may separate by the crevice between each external electrode layer corresponding to each resistive layer, it has an operation that it can prevent that external electrode layers contact and resistive layers connect electrically at the time of formation of an external electrode layer.

[0038] Invention according to claim 16 establishes the fluting and transverse groove for division in a substrate so that the field equivalent to one resistor may be divided continuously, after preparing a protective coat at least. It is what is characterized by dividing said substrate along the fluting and transverse groove for said division, and obtaining two or more resistors. In order to divide a substrate after formation of a top-face electrode layer, a resistive layer, an end-face electrode layer, a protective coat, etc. according to this manufacture approach, The need of classifying a substrate into a dimension rank is lost, and in order to form an end-face electrode layer etc., it becomes unnecessary to divide a substrate in the shape of a strip of paper

once by this in addition to the complicatedness of a process being solved. By this Two or more resistors can be obtained only by carrying out a batch rate, consequently it has an operation that a process can be simplified.

[0039] Invention according to claim 17 is characterized by forming the fluting and transverse groove for division with laser, and according to this manufacture approach, since it can form the fluting and transverse groove certainly [ the part by which laser was irradiated ] for division to a high speed, it has an operation that productivity improves.

[0040] A through tube is prepared so that invention according to claim 18 may straddle the part used as the fluting of a substrate and a transverse groove may not be straddled. It is what is characterized by connecting said conductor to a top-face electrode layer electrically, and preparing an end-face electrode layer while making said through tube fill up with a conductor. Since an end-face electrode layer can be formed in the field equivalent to one resistor surrounded by the fluting and the transverse groove according to this manufacture approach, Rather than what prepared the end-face electrode layer after dividing a substrate in the shape of a piece of an individual, it has an operation that the resistor by which only the part in which an end-face electrode layer does not project from a substrate included the end-face electrode layer can be miniaturized.

[0041] It is what is characterized by for invention according to claim 19 having prepared the through tube so that the part used as the fluting of a substrate might be straddled and a transverse groove might not be straddled, and forming an end-face electrode layer in said through tube by the spatter. Since an end-face electrode layer can be formed in the field equivalent to one resistor surrounded by the fluting and the transverse groove according to this manufacture approach, Since only the part in which an end-face electrode layer does not project from a substrate can form an end-face electrode very thinly rather than what prepared the end-face electrode layer in addition to a resistor including an end-face electrode layer being made into a miniaturization after dividing a substrate in the shape of a piece of an individual, An end-face electrode layer enters certainly in a through tube, and it has an operation that it is stabilized and an end-face electrode layer can be prepared by this.

[0042] Invention according to claim 20 has an operation that an end-face electrode layer enters into division Mizouchi certainly, it is stabilized in it by this, and an end-face electrode layer can be prepared in it since it is characterized by forming an end-face electrode layer by the spatter, and an end-face electrode layer can be formed in the fluting or transverse groove for division very thinly according to this manufacture approach.

[0043] It is what is characterized by dividing a substrate as it establishes the fluting and transverse groove for division in a substrate and makes said sheet

bridging separate from a substrate after that after invention according to claim 21 sticks a sheet bridging on a substrate. According to this manufacture approach, a location gap is caused when one side is prepared among the fluting for division, and a transverse groove. Cannot establish the slot for another division in a position, or When a substrate is divided, each piece of individual-like resistors are scattered scatteringly, and it has an operation that it can prevent that a next process becomes complicated. [0044] It is what is characterized by invention according to claim 22 using the thing containing the adhesives which have an ultraviolet curing property as a sheet bridging. Since the adhesive strength of a sheet bridging can be lost by irradiating ultraviolet rays at high speed according to this manufacture approach, Since the adhesive strength of a sheet bridging can be lost fundamentally in addition to productivity improving, it has an operation that a sheet bridging is certainly separable from a substrate. [0045] It is characterized by performing the process into which invention according to claim 23 makes a sheet bridging separate from a substrate by irradiating ultraviolet rays, and since the adhesive strength of a sheet bridging can be easily lost by irradiating ultraviolet rays according to this manufacture approach, it has an operation that a sheet bridging is easily separable from a substrate.

[0046] (Gestalt 1 of operation) The resistor in a gestalt 1 and its manufacture approach of operation are explained hereafter, referring to a drawing.

[0047] The perspective view of a resistor [ in / in <u>drawing 1</u> (a) / the gestalt 1 of operation of this invention ] and <u>drawing 1</u> (b) are these A-A line sectional views. In addition, <u>drawing 1</u> (a) is omitting the plating layer 17 mentioned later.

[0048] In drawing 1 (a) and (b), 11 is a substrate, has the notching section 12 to both ends, and consists of an ingredient of resin systems, such as resin, a resin compound, and resin mixture. The configuration of this notching section 12 is seen from the upper part of a substrate 11, and has become abbreviation rectangle—like. Of course, you may be other configurations, such as the shape of an abbreviation hemicycle. 13 is a substrate layer, is prepared in the top face of a substrate 11, and consists of an oxide which uses an alumina as a principal component. 14 is a resistive layer and is prepared in substrate 11 top face through the substrate layer 13. What is necessary is just to select the ingredient of a resistive layer 14 from ruthenium oxide, nickel—Lynn, etc. by target resistance, application, etc. [0049] In addition, if a liquid crystal polymer is used, since the thing of a suitable coefficient of thermal expansion can be easily chosen as a substrate 11 among the liquid crystal polymers from which a coefficient of thermal expansion of a

resistive layer 14 or a printed circuit board can be adjusted, and, thereby, the effectiveness that the curvature of the substrate 11 at the time of use by the difference in a coefficient of thermal expansion etc. can be prevented is acquired. Moreover, since the oxide which uses the alumina of the substrate layer 13 as a principal component can decrease invasion to the substrate 11 of moisture, it is for acquiring the effectiveness of raising the moisture resistance of the substrate 11 which consists of an ingredient of resin systems, such as a liquid crystal polymer which is generally hygroscopic. [0050] 15 is the top-face electrode layer of a pair, is prepared in the both ends of the top face of a resistive layer 14, and consists of an ingredient of a golden system. 16 is the end-face electrode layer of a pair, is formed in the notching section 12 prepared in the both ends of a substrate 11, and consists of a conductor so that it may connect with each end face of a resistive layer 14 and the top-face electrode layer 15 electrically. If the ingredient which consists of metal powder and resin as this conductor is used, since an end-face electrode layer can be calcinated at the low temperature of 130 degrees C - 240 degrees C, the effect of the heat to a resistive layer can be suppressed, and, thereby, the resistance value change under production can be made small.

[0051] Thus, by forming the end-face electrode layer 16 in the notching section 12 in which it was prepared to the both ends of a substrate 11, the effectiveness that the resistor by which only the part in which the end-face electrode layer 16 does not project from a substrate 11 included the end-face electrode layer 16 is made into a miniaturization is acquired rather than what prepared the end-face electrode layer in the substrate without the notching section. Moreover, since the end-face electrode layer 16 is formed so that the notching section 12 whole may be buried, consequently it can enlarge the cross section of an external electrode layer, it can raise bonding strength with a printed circuit board.

[0052] 17 is a plating layer, is prepared in a part of front face of the end-face electrode layer 16, and top face of the top-face electrode layer 15, and consists of a nickel-plating layer (barrier layer) 18 and a low-melt point point metal plating layer 19. Moreover, in the front face of the end-face electrode layer 16, the low-melt point point metal plating layer 19 is formed in the front face of the nickel-plating layer 18 and the nickel-plating layer 18. 20 is an external electrode layer, consists of an end-face electrode layer 16 and a plating layer 17, is formed in a part of end face of a substrate 11, and top face of the top-face electrode layer 15, and is not prepared in the rear face of a substrate 11. 21 is a protective coat, it is prepared so that a resistive layer 14 may be covered at least, and it consists of the 1st protective layer 22 which consists of oxides, such as an alumina and a silica, and the 2nd protective layer 23 which consists of a phenol system or an

epoxy resin. Moreover, the 2nd protective layer 23 is formed in the top face of the 1st protective layer 22 and the 1st protective layer 22 on the top face of a resistive layer 14.

[0053] Thus, since the stability at the time of adsorption improves when the rear face of a substrate 11 is adsorbed by the adsorption pin of an automatic mounting machine, the top-face side of a substrate 11 is turned to a printed circuit board side and it mounts in a printed circuit board by not forming the external electrode layer 20 in the rear face of a substrate 11, the effectiveness that the high rate of mounting is securable is acquired. Moreover, the 1st protective layer 22 which a protective coat 21 becomes from oxides with thermal resistance, such as an alumina and a silica, Since a resistive layer 14 is covered by the protective coat 21 which was excellent in thermal resistance and moisture resistance by constituting from the 2nd protective layer 23 which consists of the existing phenol system or epoxy resin of the moisture resistance formed in the top face of the 1st protective layer 22, A resistive layer 14 does not need to be influenced of heat or moisture, and, thereby, the effectiveness that the rate of a change in resistance at the time of use can be made small is also acquired. Furthermore, since the touch area of the external electrode layer 20 and the top-face electrode layer 15 becomes large by forming the external electrode layer 16 in the top face of the top-face electrode layer 15, even if it receives environmental loads, such as a thermal shock, the increment in contact resistance in the meantime can be suppressed, and thereby, since a resistive layer 14 can make small the rate of the increment of the contact resistance to the resistance of a resistive layer 14 also in low resistance value, the effectiveness that the rate of a change in resistance can be made low is also acquired.

[0054] About the resistor in the gestalt 1 of operation of this invention constituted as mentioned above, the manufacture approach is explained below, referring to a drawing.

[0055] <u>Drawing 2</u> – <u>drawing 8</u> are drawings showing the manufacture approach of the resistor in the gestalt 1 of operation of this invention. In addition, in each drawing, (b) is a plan, (a) is the B–B line sectional view of (b), and (d) and (f of a plan, (c), and (e)) are the B–B line sectional views of (d) and (f) like this, respectively.

[0056] First, as shown in <u>drawing 2</u> (a) and (b), the substrate 11 which consists of an ingredient of resin systems, such as resin, a resin compound, and resin mixture, is prepared (in addition, this substrate 11 says the substrate of the shape of a bigger sheet than one resistor, in order to manufacture two or more resistors.). In order to obtain one resistor, it is necessary to divide the substrate of the shape of this sheet.

[0057] In addition, the thickness of a substrate 11 has 0.05mm - 0.25

desirablemm. Since the substrate 11 is as thin as 0.25mm or less, wear of the cutting edge at the time of substrate cutting can be suppressed small. However, if set to 0.05mm or less, it will be hard to form a resistive layer 14 etc., or the handling of substrate 11 the very thing becomes difficult. [0058] Next, as shown in drawing 2 (c) and (d), the substrate layer 13 which consists of oxides, such as an alumina, is formed in the top face of a substrate 11.

[0059] Next, as shown in <u>drawing 2</u> (e) and (f), pattern NINGU of the substrate layer 13 is carried out according to a FOTORISO process. At this time, it leaves except the periphery section (part in which the fluting 28 for division mentioned later and a transverse groove 29 are formed) of the field equivalent to one resistor (part which has one independent resistive layer 14).

[0060] Next, as shown in <u>drawing 3</u> (a) and (b), a resistive layer 14 is formed in the top face of the substrate layer 13 and the substrate 11 which does not have the substrate layer 13 in a top face by the spatter.

[0061] Next, as shown in <u>drawing 3</u> (c) and (d), the top-face electrode layer 15 which consists of an ingredient of a golden system by the spatter all over resistive layer 14 top face is formed. In addition, a rear-face electrode may be prepared in the rear face of a substrate 11 if needed.

[0062] Next, as shown in <u>drawing 3</u> (e) and (f), pattern NINGU of the top-face electrode layer 15 is carried out with a FOTORISO method of construction. At this time, the top-face electrode layer 15 is formed in the both ends of resistive layer 14 top face in the field equivalent to one resistor (part which has one independent resistive layer 14). It is made for the top-face electrode layer 15 not to continue in the field equivalent to one more resistor (part which has one independent resistive layer 14).

[0063] Next, as shown in <u>drawing 4</u> (a) and (b), in order to make it target

resistance, pattern NINGU of the resistive layer 14 is carried out with a FOTORISO process, laser, etc. if needed. Furthermore, it is made to be formed only in substrate layer 13 top face which remains in addition to the periphery section of the field in which a resistive layer 14 is equivalent to one resistor (part which has one independent resistive layer 14). It is made for the top-face electrode layer 15 formed in the top face of a resistive layer 14 and a resistive layer 14 not to straddle a transverse groove 29 ranging over the fluting 28 for division prepared at a back process at this time.

[0064] After forming the top-face electrode layer 15 and a resistive layer 14

by the spatter, thus, by having been made to carry out pattern NINGU with a FOTORISO method of construction at a predetermined configuration, respectively Since pattern formation of the resistive layer 14 is carried out with high precision by the FOTORISO process in addition to becoming easy to divide a substrate 11 in the fluting 28 or transverse groove 29 for division

since the top-face electrode layer 15 and a resistive layer 14 can be formed thinly, Effective area of a resistive layer 14 can be enlarged, and thereby, even if high power is impressed, the effectiveness that the rate of a change in resistance can be made low is acquired.

[0065] Next, as shown in <u>drawing 4</u> (c) and (d), in order to adjust the resistance between the top-face electrode layers 15 in the field equivalent to one resistor (part which has one independent resistive layer 14), the trimming slot 24 is formed by laser trimming if needed.

[0066] Next, as shown in <u>drawing 4</u> (e) and (f), the resist layer 25 is formed in some top faces of the top-face electrode layer 15 by screen-stencil so that a resistive layer 14 may be exposed at least. It hardens at 150 degrees C and the temperature for 10 minutes so that the resist layer 25 may be stabilized after this.

[0067] Next, as shown in <u>drawing 5</u> (a) and (b), the 1st protective layer 22 which consists of oxides, such as an alumina, by the spatter is formed in a part of exposed resistive layer 14, top—face electrode layer 15, and the top face of the resist layer 25.

[0068] Next, as shown in <u>drawing 5</u> (c) and (d), lift off of the resist layer 25 is carried out, and pattern NINGU of the 1st protective layer 22 is carried out. [0069] Thus, since the substrate layer 13 and a protective coat 21 can be precisely formed by forming the 1st protective layer 22 by the spatter at least among the substrate layer 13 and a protective coat 21, moisture stops being able to enter easily to a resistive layer 14, and, thereby, the effectiveness that a resistive layer is stabilized is acquired.

[0070] Next, as shown in <u>drawing 5</u> (e) and (f), the 2nd protective layer 23 which consists of resin is formed in the top face of the 1st protective layer 22 by screen—stencil. It hardens at 180 degrees C and the temperature for 30 minutes so that the 2nd protective layer 23 may be stabilized after this. At this time, the protective coat 21 which consists of the 1st protective layer 22 and 2nd protective layer 23 covers a resistive layer 14 at least. [0071] Thus, the 2nd protective layer 23 can be cheaply formed by forming the 2nd protective layer 23 by screen—stencil.

[0072] Next, as shown in <u>drawing 6</u> (a) and (b), a through tube 26 is formed in the both ends of the substrate 11 in the field equivalent to one resistor (part which has one independent resistive layer 14). Namely, what is necessary is just to make it a through tube 26 not straddle a transverse groove 29 ranging over the fluting 28 for division prepared at a back process. In addition, this through tube 26 is equivalent to the notching section 12 in <u>drawing 1</u>. [0073] Next, as shown in <u>drawing 6</u> (c) and (d), it is filled up with the mixed paste which becomes a through tube 26 from metal powder and resin, and the end–face electrode layer 16 is formed. It hardens at 200 degrees C and the temperature for 30 minutes so that 16 of an end–face electrode layer

may be stabilized after this. At this time, the end-face electrode layer 16 is formed in the both-ends side of a substrate 11 so that it may connect with each end face of a resistive layer 14 and the top-face electrode layer 15 electrically.

[0074] Thus, a through tube 26 is formed so that the part used as the fluting 28 of a substrate 11 may be straddled and a transverse groove 29 may not be straddled. By making it connect with the top-face electrode layer 15 electrically, and having formed the end-face electrode layer 16, while making the through tube 26 fill up with a conductor Since the end-face electrode layer 16 can be formed in the field equivalent to one resistor surrounded by the fluting 28 and the transverse groove 29, Rather than what formed the end-face electrode layer 16 after dividing a substrate 11 in the shape of a piece of an individual, the end-face electrode layer 16 can miniaturize the resistor by which only the part which does not project from a substrate 11 included the end-face electrode layer 16.

[0075] Furthermore, since it formed by stiffening the mixed paste which becomes a through tube 26 from metal powder and resin about the end-face electrode layer 16, the end-face electrode layer 16 can be calcinated at the low temperature of 130 degrees C – 240 degrees C, thereby, the effect of the heat to a resistive layer 14 can be suppressed, and the effectiveness that the resistance value change under production can be made small is acquired.

[0076] Moreover, the end-face electrode layer 16 may be formed by the spatter instead of being filled up with the conductor which becomes a through tube 26 from metal powder and resin as described above. Since in addition to the effectiveness described above at this time the end-face electrode layer 16 can be formed very thinly even if a through tube 26 is small, the end-face electrode layer 16 enters certainly in a through tube 26, and the effectiveness that it is stabilized and the end-face electrode layer 16 can be formed by this can also be expected.

[0077] Next, after adhesives stick on it the sheet bridging 27 by which the adhesives which have an ultraviolet curing property were formed in one side all over substrate 11 inferior surface of tongue as they contact a substrate 11 as shown in <u>drawing 6</u> (e) and (f), the fluting 28 for division is formed. It is made for a resistive layer 14, the top—face electrode layer 15, and the end—face electrode layer 16 to straddle a fluting 28 at this time.

[0078] Next, as shown in <u>drawing 7</u> (a) and (b), the transverse groove 29 for division is formed. It is made for a resistive layer 14, the top-face electrode layer 15, and the end-face electrode layer 16 not to straddle a transverse groove 29 at this time.

[0079] Of course, after preparing what is formed at the end among components, such as a resistive layer 14 and the top-face electrode layer

15, (protective coat 21 in this case), after the direction which formed the fluting 28 for division and the transverse groove 29, and divided the substrate 11 divides a substrate 11, it is efficient rather than it prepares each one component at a time.

[0080] The fluting 28 for this division and a transverse groove 29 are formed a dicing process and by irradiating an excimer laser. In addition, if an excimer laser is used, since the fluting 28 and transverse groove 29 certainly [ the part by which laser was irradiated ] for division to a high speed can be formed, productivity will improve.

[0081] Moreover, the fluting 28 and transverse groove 29 for division are formed in a part of substrate 11 and sheet bridging 27. Of course, the fluting 28 and transverse groove 29 for division are formed to the middle of a substrate 11, and a substrate 11 is divided and you may make it obtain the resistor of the shape of two or more piece of an individual with a dicing method of construction etc. after that.

[0082] In addition, the end-face electrode layer 16 may be formed in the fluting 28 for division, and a transverse groove 29 by the spatter instead of forming the end-face electrode layer 16 by being filled up with the conductor which becomes a through tube 26 from metal powder and resin, or carrying out a spatter, as described above, without forming a through tube 26. Since the end-face electrode layer 16 can be formed very thinly at this time, the end-face electrode layer 16 enters into division Mizouchi certainly, thereby, it is stabilized and the end-face electrode layer 16 can be formed. [0083] Next, as shown in <u>drawing 7</u> (c) and (d), irradiate ultraviolet rays, the sheet bridging 27 is made to separate from a substrate 11, a substrate 11 is divided along the fluting 28 and transverse groove 29 for division, and it divides into the resistor of the shape of two or more piece of an individual. [0084] Thus, by having established the fluting 28 and transverse groove 29 for division in the substrate 11, making the sheet bridging 27 separate from a substrate 11 after that, and having divided the substrate 11, after sticking the sheet bridging 27 on a substrate 11 A location gap is caused when one side is prepared among the fluting 28 for division, and a transverse groove 29. Cannot establish the slot for another division in a position, or When a substrate 11 is divided, each piece of individual-like resistors are scattered scatteringly, and the effectiveness that it can prevent that a next process becomes complicated is acquired. Moreover, the adhesive strength of the sheet bridging 27 can be lost at high speed by irradiating ultraviolet rays, since the thing containing the adhesives which have an ultraviolet curing property as a sheet bridging 27 was used, and thereby, since the adhesive strength of the sheet bridging 27 can be lost fundamentally in addition to productivity improving, the sheet bridging 27 is certainly separable from a substrate 11. Furthermore, since the process into which the sheet bridging

27 is made to separate from a substrate 11 is performed by irradiating ultraviolet rays, by irradiating ultraviolet rays, it can lose the adhesive strength of the sheet bridging 27 easily, and, thereby, can separate the sheet bridging 27 from a substrate 11 easily.

[0085] Finally, as shown in <u>drawing 8</u> (a) and (b), the plating layer 17 which consists of a nickel-plating layer 18 and a low-melt point point metal plating layer 19 is formed in the front face of the end-face electrode layer 16, and the exposed top face of the top-face electrode layer 15.

[0086] Since the substrate 11 which consists of an ingredient of a resin system softer than an alumina was used for the resistor in the gestalt 1 of operation of above-mentioned this invention, wear of the cutting edge for substrate cutting can be suppressed, and, thereby, the effectiveness that the cutting cost of a substrate can be held down is acquired.

[0087] Moreover, in order to divide a substrate 11 after formation of the top-face electrode layer 15, a resistive layer 14, the end-face electrode layer 16, a protective coat 21, etc., the need of classifying a substrate 11 into a dimension rank is lost, and, thereby, the effectiveness that the complicatedness of a process is solved is also acquired.

[0088] Furthermore, in order to divide a substrate 11 after formation of the top-face electrode layer 15, a resistive layer 14, the end-face electrode layer 16, a protective coat 21, etc., in order to form the end-face electrode layer 16 etc., it is not necessary to divide a substrate 11 in the shape of a strip of paper once, the resistor of the shape of two or more piece of an individual can be obtained only by carrying out a batch rate by this, and, thereby, the effectiveness that a process can be simplified is also acquired. [0089] In addition, in <u>drawing 7</u> and <u>drawing 8</u>, although two or more things with which two resistors (part which has one independent resistive layer 14) of the shape of a piece of an individual which became independent by the transverse groove 29 were connected are obtained, as shown in drawing 1, two or more resistors which have one independent resistive layer 14 by the transverse groove 29 may be made to be obtained. Of course, the above-mentioned effectiveness can be said to all of that (multiple-string chip resistor with which the resistive layer which plurality became independent of is one unit) with which the resistor which has one independent resistive layer, and two or more resistors which have one independent resistive layer like the resistor in the gestalt 2 of operation mentioned later were connected.

[0090] (Gestalt 2 of operation) The resistor in a gestalt 2 and its manufacture approach of operation are explained hereafter, referring to a drawing.

[0091] The perspective view of a resistor [ in / in <u>drawing 9</u> (a) / the gestalt 2 of operation of this invention ] and <u>drawing 9</u> (b) are these C-C line

sectional views. In addition, <u>drawing 9</u> (a) is omitting the protective coat 21 mentioned later. Moreover, the resistor in the gestalt 2 of operation of this invention is a multiple-string chip resistor with which the resistive layer which the plurality which is one sort of a resistor became independent of is one unit.

[0092] In drawing 9 (a) and (b), 11 is a substrate, has a crevice 30 to both ends, and consists of an ingredient of resin systems, such as resin, a resin compound, and resin mixture. The configuration of this crevice 30 is seen from the upper part of a substrate 11, and has become \*\*\*\* hemicycle-like. Of course, you may be other configurations, such as the shape of a rectangle. 13 is a substrate layer, is prepared in the top face of a substrate 11, and consists of an oxide which uses an alumina as a principal component. 14 is two or more resistive layers, and is prepared in substrate 11 top face through the substrate layer 13. What is necessary is just to select the ingredient of a resistive layer 14 from ruthenium oxide, nickel-Lynn, etc. by target resistance, application, etc. Moreover, two or more resistive layers 14 become independent, respectively, and each other is stationed at the juxtaposition condition.

[0093] In addition, if a liquid crystal polymer is used, since the thing of a suitable coefficient of thermal expansion can be easily chosen as a substrate 11 among the liquid crystal polymers from which a coefficient of thermal expansion differs, relation with the coefficient of thermal expansion of a resistive layer 14 or a printed circuit board can be adjusted, and, thereby, the effectiveness that the curvature of the substrate 11 at the time of use by the difference in a coefficient of thermal expansion etc. can be prevented is acquired. Moreover, since the oxide which uses the alumina of the substrate layer 13 as a principal component can decrease invasion to the substrate 11 of moisture, it is for acquiring the effectiveness of raising the moisture resistance of the substrate 11 which consists of an ingredient of resin systems, such as a liquid crystal polymer which is generally hygroscopic. [0094] 15 is two or more pairs of top-face electrode layers, is prepared in the both ends of the top face of each resistive layer 14, and consists of an ingredient of a golden system. 16 is two or more pairs of end-face electrode layers, it is formed so that it may connect with each end face of the end-face electrode layer 16 of a pair, and the resistive layer 14 of the pair which corresponds, respectively and the top-face electrode layer 15 of a pair electrically, and it consists of a conductor. If the ingredient which consists of metal powder and resin as this conductor is used, since an end-face electrode layer can be calcinated at the low temperature of 130 degrees C -240 degrees C, the effect of the heat to a resistive layer can be suppressed, and, thereby, the resistance value change under production can be made small.

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[0095] 17 is two or more plating layers, is prepared in a part of front face of each end-face electrode layer 16, and top face of each top-face electrode layer 15 corresponding to each of this end-face electrode layer 16, and consists of a nickel-plating layer (barrier layer) 18 and a low-melt point point metal plating layer 19. Moreover, in the front face of each end-face electrode layer 16, the low-melt point point metal plating layer 19 is formed in the front face of the nickel-plating layer 18 and the nickel-plating layer 18. 20 is two or more external electrode layers, and each external electrode layer 20 consists of an end-face electrode layer 16 and a plating layer 17, is formed in a part of end face of a substrate 11, and top face of the top-face electrode layer 15, and is not prepared in the rear face of a substrate 11. Moreover, the crevice 30 mentioned above is formed in the part located between each external electrode layer 20 in the end face of a substrate 11. 21 is a protective coat, it is prepared so that all the resistive layers 14 may be covered at least, and it consists of the 1st protective layer 22 which consists of oxides, such as an alumina and a silica, and the 2nd protective layer 23 which consists of a phenol system or an epoxy resin. Moreover, the 2nd protective layer 23 is formed in the top face of the 1st protective layer 22 and the 1st protective layer 22 on the top face of each resistive layer 14. Moreover, the top face of each external electrode layer 20 is prepared more nearly up than the top face of a protective coat 21. [0096] Thus, since the stability at the time of adsorption improves when the rear face of a substrate 11 is adsorbed by the adsorption pin of an automatic mounting machine, the top-face side of a substrate 11 is turned to a printed circuit board side and it mounts in a printed circuit board by not forming the external electrode layer 20 in the rear face of a substrate 11, the effectiveness that the high rate of mounting is securable is acquired. Moreover, the 1st protective layer 22 which a protective coat 21 becomes from oxides with thermal resistance, such as an alumina and a silica, Since a resistive layer 14 is covered by the protective coat 21 which was excellent in thermal resistance and moisture resistance by constituting from the 2nd protective layer 23 which consists of the existing phenol system or epoxy resin of the moisture resistance formed in the top face of the 1st protective layer 22, A resistive layer 14 does not need to be influenced of heat or moisture, and, thereby, the effectiveness that the rate of a change in resistance at the time of use can be made small is also acquired. Furthermore, since the touch area of the external electrode layer 20 and the top-face electrode layer 15 becomes large by forming the external electrode

layer 16 in the top face of the top-face electrode layer 15, even if it receives

resistance in the meantime can be suppressed, and thereby, since a resistive

layer 14 can make small the rate of the increment of the contact resistance

environmental loads, such as a thermal shock, the increment in contact

to the resistance of a resistive layer 14 also in low resistance value, the effectiveness that the rate of a change in resistance can be made low is also acquired.

[0097] Moreover, since the crevice 30 was formed in the part located between each external electrode layer 20 in the end face of a substrate 11, In the multiple-string chip resistor with which the resistive layer which plurality like the resistor in the gestalt 2 of operation of this this invention became independent of is one unit The distance in the end face of a substrate (not being the creeping distance) 11 separates by the crevice 30 between each external electrode layer 20 corresponding to each resistive layer 14. By this The effectiveness that it can prevent that external electrode layer 20 comrades contact and resistive layer 14 comrades connect electrically at the time of formation of the external electrode layer 20 is acquired.

[0098] Furthermore, since the top face of the external electrode layer 20 was prepared more nearly up than the top face of a protective coat 21, even if it turns the top-face side of a substrate 11 to a printed circuit board side, in order that the top face of the external electrode 20 may contact a printed circuit board, whichever it turns [ of the vertical side of a substrate ] to a printed circuit board side, the effectiveness that mounting becomes possible is also acquired.

[0099] About the resistor in the gestalt 2 of operation of this invention constituted as mentioned above, the manufacture approach is explained below, referring to a drawing.

[0100] <u>Drawing 10</u> – <u>drawing 16</u> are drawings showing the manufacture approach of the resistor in the gestalt 2 of operation of this invention. In addition, in each drawing, (b) is a plan, (a) is D–D line sectional view of (b), and (d) and (f of a plan, (c), and (e)) are D–D line sectional views of (d) and (f) like this, respectively.

[0101] First, as shown in <u>drawing 10</u> (a) and (b), the substrate 11 which consists of an ingredient of resin systems, such as resin, a resin compound, and resin mixture, is prepared (in addition, this substrate 11 says the substrate of the shape of a bigger sheet than one resistor, in order to manufacture two or more resistors.). In order to obtain one resistor, it is necessary to divide the substrate of the shape of this sheet.

[0102] Next, as shown in <u>drawing 10</u> (c) and (d), the substrate layer 13 which consists of oxides, such as an alumina, is formed in the top face of a substrate 11.

[0103] Next, as shown in <u>drawing 10</u> (e) and (f), pattern NINGU of the substrate layer 13 is carried out with a FOTORISO method of construction. At this time, it leaves except the periphery section (part in which the fluting 28 for division mentioned later and a transverse groove 29 are formed) of the

field equivalent to one resistor (part which has one independent resistive layer 14).

[0104] Next, as shown in <u>drawing 11</u> (a) and (b), a resistive layer 14 is formed in the top face of the substrate layer 13 and the substrate 11 which does not have the substrate layer 13 in a top face by the spatter.

[0105] Next, as shown in <u>drawing 11</u> (c) and (d), the top-face electrode layer 15 which consists of an ingredient of a golden system by the spatter all over resistive layer 14 top face is formed. In addition, a rear-face electrode may be prepared in the rear face of a substrate 11 if needed.

[0106] Next, as shown in <u>drawing 11</u> (e) and (f), pattern NINGU of the top-face electrode layer 15 is carried out with a FOTORISO method of construction. At this time, the top-face electrode layer 15 is formed in the both ends of resistive layer 14 top face in the field equivalent to one resistor (part which has one independent resistive layer 14). It is made for the top-face electrode layer 15 not to continue in the field equivalent to one more resistor (part which has one independent resistive layer 14).

[0107] Next, as shown in <u>drawing 12</u> (a) and (b), in order to make it target resistance, pattern NINGU of the resistive layer 14 is carried out with a FOTORISO method of construction, laser, etc. if needed. Furthermore, it is made to be formed only in substrate layer 13 top face which remains in addition to the periphery section of the field in which a resistive layer 14 is equivalent to one resistor (part which has one independent resistive layer 14). It is made for the top-face electrode layer 15 formed in the top face of a resistive layer 14 and a resistive layer 14 not to straddle a transverse groove 29 ranging over the fluting 28 for division prepared at a back process at this time.

[0108] After forming the top-face electrode layer 15 and a resistive layer 14 by the spatter, thus, by having been made to carry out pattern NINGU with a FOTORISO method of construction at a predetermined configuration, respectively Since pattern formation of the resistive layer 14 is carried out with high precision by the FOTORISO process in addition to becoming easy to divide a substrate 11 in the fluting 28 or transverse groove 29 for division since the top-face electrode layer 15 and a resistive layer 14 can be formed thinly, Effective area of a resistive layer 14 can be enlarged, and thereby, even if high power is impressed, the effectiveness that the rate of a change in resistance can be made low is acquired.

[0109] Next, as shown in <u>drawing 12</u> (c) and (d), in order to adjust the resistance between the top-face electrode layers 15 in the field equivalent to one resistor (part which has one independent resistive layer 14), the trimming slot 24 is formed by laser trimming if needed.

[0110] Next, as shown in <u>drawing 12</u> (e) and (f), 1st resist layer 25a is prepared in some top faces of the top-face electrode layer 15 by

screen-stencil so that a resistive layer 14 may be exposed at least. It hardens at 150 degrees C and the temperature for 10 minutes so that 1st resist layer 25a may be stabilized after this.

[0111] Next, as shown in <u>drawing 13</u> (a) and (b), the 1st protective layer 22 which consists of oxides, such as an alumina, by the spatter is formed in a part of exposed resistive layer 14, top—face electrode layer 15, and the top face of 1st resist layer 25a.

[0112] Next, as shown in <u>drawing 13</u> (c) and (d), lift off of the 1st resist layer 25a is carried out, and pattern NINGU of the 1st protective layer 22 is carried out.

[0113] Thus, since the substrate layer 13 and a protective coat 21 can be precisely formed by forming the 1st protective layer 22 by the spatter at least among the substrate layer 13 and a protective coat 21, moisture stops being able to enter easily to a resistive layer 14, and, thereby, the effectiveness that a resistive layer is stabilized is acquired.

[0114] Next, as shown in <u>drawing 13</u> (e) and (f), the 2nd protective layer 23 which consists of resin is formed in the top face of the 1st protective layer 22 by screen-stencil. It hardens at 180 degrees C and the temperature for 30 minutes so that the 2nd protective layer 23 may be stabilized after this. At this time, the protective coat 21 which consists of the 1st protective layer 22 and 2nd protective layer 23 covers all the resistive layers 14 at least.

[0115] Thus, the 2nd protective layer 23 can be cheaply formed by forming the 2nd protective layer 23 by screen-stencil.

[0116] Next, as shown in <u>drawing 14</u> (a) and (b), the 2nd resist layer 31 is formed so that a protective coat 21 may be covered at least.

[0117] Next, after adhesives stick on it the sheet bridging 27 by which the adhesives which have an ultraviolet curing property were formed in one side all over substrate 11 inferior surface of tongue as they contact a substrate 11 as shown in drawing 14 (c) and (d), the fluting 28 for division is formed. It is made for a resistive layer 14, the top-face electrode layer 15, and the end-face electrode layer 16 mentioned later to straddle a fluting 28 at this time.

[0118] Next, as shown in <u>drawing 14</u> (e) and (f), the end-face electrode layer 16 is formed by the spatter so that the 2nd resist layer 31 exposed to substrate 11 top face, the top-face electrode layer 15, and a fluting 28 may be covered. At this time, the end-face electrode layer 16 enters in a fluting 28.

[0119] Thus, the effectiveness that the end-face electrode layer 16 enters certainly in the division slot 28, it is stabilized in it by this, and the end-face electrode layer 16 can be formed in it since the end-face electrode layer 16 can be formed in the fluting 28 for division very thinly by having formed the

end-face electrode layer 16 by the spatter is acquired.

[0120] Next, as shown in <u>drawing 15</u> (a) and (b), lift off of the 2nd resist layer 31 is carried out, and all the protective coats 21 are exposed.

[0121] Next, as shown in <u>drawing 15</u> (c) and (d), the transverse groove 29 for division is formed. It is made for a resistive layer 14, the top-face electrode layer 15, and the end-face electrode layer 16 not to straddle a transverse groove 29 at this time.

[0122] The fluting 28 for this division and a transverse groove 29 are formed a dicing method of construction and by irradiating an excimer laser. In addition, if an excimer laser is used, since the fluting 28 and transverse groove 29 certainly [ the part by which laser was irradiated ] for division to a high speed can be formed, productivity will improve.

[0123] Moreover, the fluting 28 and transverse groove 29 for division are formed in a part of substrate 11 and sheet bridging 27. Of course, the fluting 28 and transverse groove 29 for division are formed in a substrate 11 to the middle, and a substrate 11 is divided and you may make it obtain two or more resistors with a dicing method of construction etc. after that.

[0124] In addition, the end-face electrode layer 16 may be formed by being filled up with the conductor which becomes a through tube 26 from metal powder and resin like the resistor in the gestalt 1 of operation of this invention, or carrying out a spatter instead of forming the end-face electrode layer 16 in the fluting 28 for division, and a transverse groove 29 by the spatter, as described above. Since the end-face electrode layer 16 can be formed in the field which is equivalent to one resistor surrounded by the fluting 28 and the transverse groove 29 at this time, the end-face electrode layer 16 can miniaturize the resistor by which only the part which does not project from a substrate 11 included the end-face electrode layer 16 rather than what formed the end-face electrode layer 16 after dividing a substrate 11 in the shape of a piece of an individual. Moreover, if it forms so that the end-face electrode layer 16 may bury the through tube 26 (equivalent to the notching section 12) whole, since the cross section of the external electrode layer 20 can be enlarged, bonding strength with a printed circuit board can be raised.

[0125] Thus, if a through tube 26 is formed and the end-face electrode layer 16 is formed in this part, the notching section 12 and a crevice 30 will be formed in the end face of a substrate 11.

[0126] Next, between the fields equivalent to one resistor (part which has one independent resistive layer 14), as shown in <u>drawing 15</u> (e) and (f), a crevice 30 is formed so that a transverse groove 29 may be included. It is made for the fields equivalent to one resistor (part which has one independent resistive layer 14) not to separate by the crevice 30 at this time.

[0127] Next, as shown in <u>drawing 16</u> (a) and (b), irradiate ultraviolet rays, the sheet bridging 27 is made to separate from a substrate 11, a substrate 11 is divided along the fluting 28 for division, and the transverse groove 29 in which the crevice 30 is not formed, and it divides into two or more resistors. [0128] In addition, the number of the independent resistive layers 14 contained in one unit can be selected by specifying the location of the transverse groove 29 in which a crevice 30 is established.

[0129] Thus, by having established the fluting 28 and transverse groove 29 for division in the substrate 11, making the sheet bridging 27 separate from a substrate 11 after that, and having divided the substrate 11, after sticking the sheet bridging 27 on a substrate 11 A location gap is caused when one side is prepared among the fluting 28 for division, and a transverse groove 29. Cannot establish the slot for another division in a position, or When a substrate 11 is divided, each piece of individual-like resistors are scattered scatteringly, and the effectiveness that it can prevent that a next process becomes complicated is acquired. Moreover, the adhesive strength of the sheet bridging 27 can be lost at high speed by irradiating ultraviolet rays, since the thing containing the adhesives which have an ultraviolet curing property as a sheet bridging 27 was used, and thereby, since the adhesive strength of the sheet bridging 27 can be lost fundamentally in addition to productivity improving, the sheet bridging 27 is certainly separable from a substrate 11. Furthermore, since the process into which the sheet bridging 27 is made to separate from a substrate 11 is performed by irradiating ultraviolet rays, by irradiating ultraviolet rays, it can lose the adhesive strength of the sheet bridging 27 easily, and, thereby, can separate the sheet bridging 27 from a substrate 11 easily.

[0130] Finally, as shown in <u>drawing 16</u> (c) and (d), the plating layer 17 which consists of a nickel-plating layer 18 and a low-melt point point metal plating layer 19 is formed in the front face of the end-face electrode layer 16, and the exposed top face of the top-face electrode layer 15.

[0131] It is made for the top face of each external electrode layer 20 to become the upper part from the top face of a protective coat 21 at this time.

[0132] <u>Drawing 17</u> is the sectional view showing what turned the top-face side of a substrate 11 to the printed circuit board 32, and mounted the resistor in the gestalt 2 of operation of this invention in the printed circuit board 32.

[0133] Usually, although the inferior-surface-of-tongue side of a substrate is turned to a printed circuit board side, and an external electrode is contacted to a printed circuit board and mounted, in order that the top face of the external electrode 20 may contact a printed circuit board 32 through the solder 33 for mounting even if it turns the top-face side of a substrate 11 to

a printed circuit board side so that clearly from <u>drawing 17</u>, mounting becomes possible whichever it turns [ of the vertical side of a substrate ] to a printed circuit board side. In addition, such effectiveness can be said to both the resistor which has one independent resistive layer, and the multiple-string chip resistor with which the resistive layer which plurality became independent of is one unit.

[0134] Since the substrate 11 which consists of an ingredient of a resin system softer than an alumina was used for the resistor in the gestalt 2 of operation of above—mentioned this invention, wear of the cutting edge for substrate cutting can be suppressed, and, thereby, the effectiveness that the cutting cost of a substrate can be held down is acquired.

[0135] Moreover, in order to divide a substrate 11 after formation of the top-face electrode layer 15, a resistive layer 14, the end-face electrode layer 16, a protective coat 21, etc., the need of classifying a substrate 11 into a dimension rank is lost, and, thereby, the effectiveness that the complicatedness of a process is solved is also acquired.

[0136] Furthermore, in order to divide a substrate 11 after formation of the top—face electrode layer 15, a resistive layer 14, the end—face electrode layer 16, a protective coat 21, etc., in order to form the end—face electrode layer 16 etc., it is not necessary to divide a substrate 11 in the shape of a strip of paper once, the resistor of the shape of two or more piece of an individual can be obtained only by carrying out a batch rate by this, and, thereby, the effectiveness that a process can be simplified is also acquired. [0137] In addition, although the resistor in the gestalt 2 of operation of above—mentioned this invention explained the multiple—string chip resistor with which two independent resistive layers are one unit, it cannot be overemphasized that the effectiveness that the independent resistive layer is the same also about three or more multiple—string chip resistors is acquired. [0138]

[Effect of the Invention] It is what is characterized by for the resistor of this invention having a substrate, the resistive layer prepared in the top face of said substrate, and the top-face electrode layer of the pair prepared in the both ends of the top face of said resistive layer, and said substrate consisting of an ingredient of a resin system as mentioned above. Since the substrate which consists of an ingredient of a resin system softer than an alumina was used according to this configuration, wear of the cutting edge for substrate cutting can be suppressed, and, thereby, operation that the cutting cost of a substrate can be held down is acquired.

[Translation done.]

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## **DESCRIPTION OF DRAWINGS**

[Brief Description of the Drawings]

[Drawing 1] (a) The perspective view of the resistor in the gestalt 1 of operation of this invention

(b) The A-A line sectional view of this resistor

[Drawing 2] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 3] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 4] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 5] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 6] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 7] (a) Drawing showing the manufacture approach of the -(d) said resistor

[Drawing 8] Drawing showing the manufacture approach of (a) and the (b) said resistor

[Drawing 9] (a) The perspective view of the resistor in the gestalt 2 of operation of this invention

(b) The C-C line sectional view of this resistor

[Drawing 10] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 11] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 12] (a) Drawing showing the manufacture approach of the –(f) said resistor

[Drawing 13] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 14] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 15] (a) Drawing showing the manufacture approach of the -(f) said resistor

[Drawing 16] (a) Drawing showing the manufacture approach of the -(d) said resistor

[Drawing 17] The sectional view showing what turned the top-face side of a substrate to the printed circuit board, and mounted this resistor in the printed circuit board

[Drawing 18] (a) The perspective view of the conventional resistor

(b) The E-E line sectional view of this resistor

[Drawing 19] Drawing showing the manufacture approach of (a) and the (b) said resistor

[Drawing 20] Drawing showing the manufacture approach of (a) and the (b) said resistor

[Description of Notations]

- 11 Substrate
- 12 Notching Section
- 13 Substrate Layer
- 14 Resistive Layer
- 15 Top-Face Electrode Layer
- 16 End-Face Electrode Layer
- 17 Plating Layer
- 20 External Electrode Layer
- 21 Protective Coat
- 22 1st Protective Layer
- 23 2nd Protective Layer
- 26 Through Tube
- 27 Sheet Bridging
- 28 Fluting
- 29 Transverse Groove
- 30 Crevice

[Translation done.]

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# **DRAWINGS**

# [Drawing 1]

11基板

12 切り欠き部

13 下地層

4 抵抗層

15 上面電極層

16 端面電極層

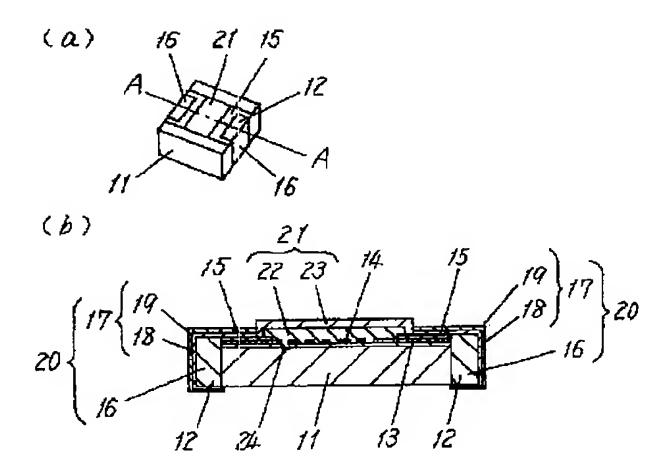
17 めっき層

20 外部電極層

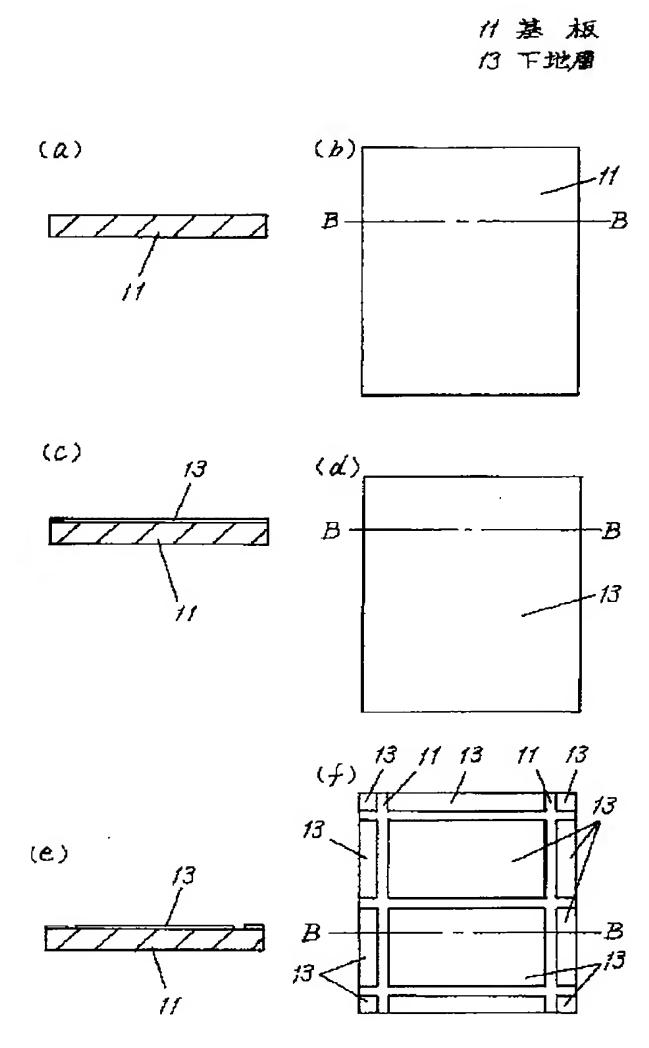
21 保護膜

27 第10/保護層

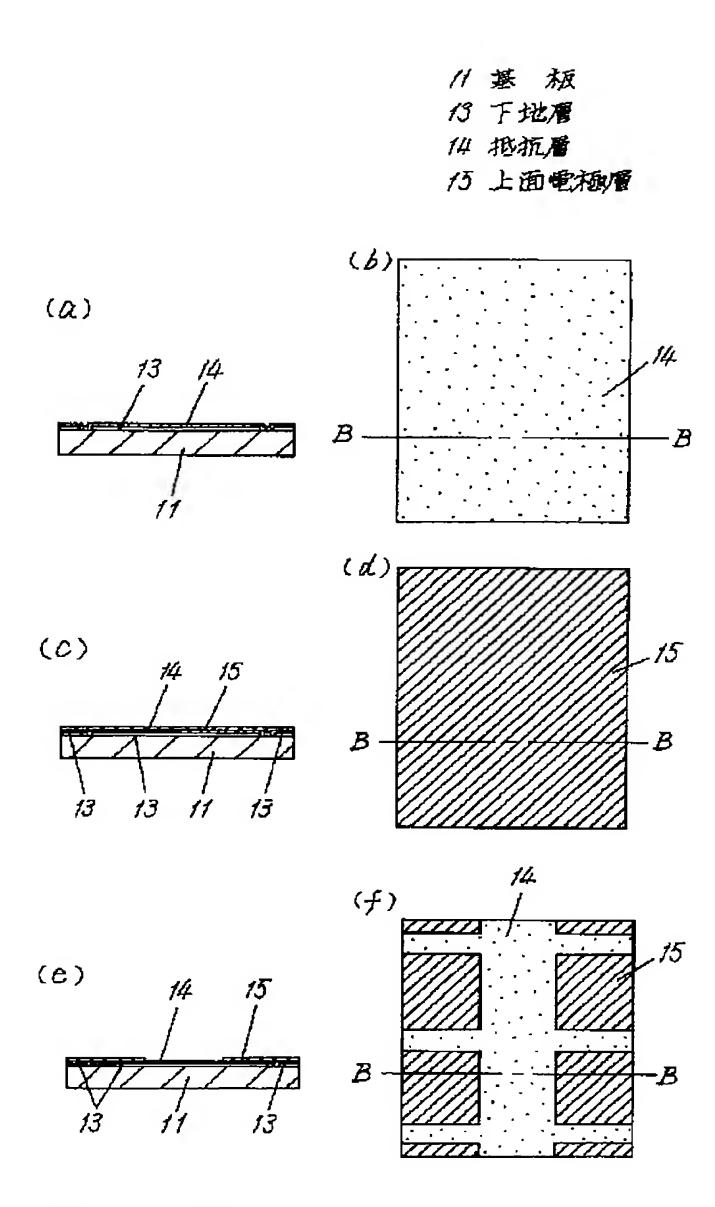
23 第20保護層



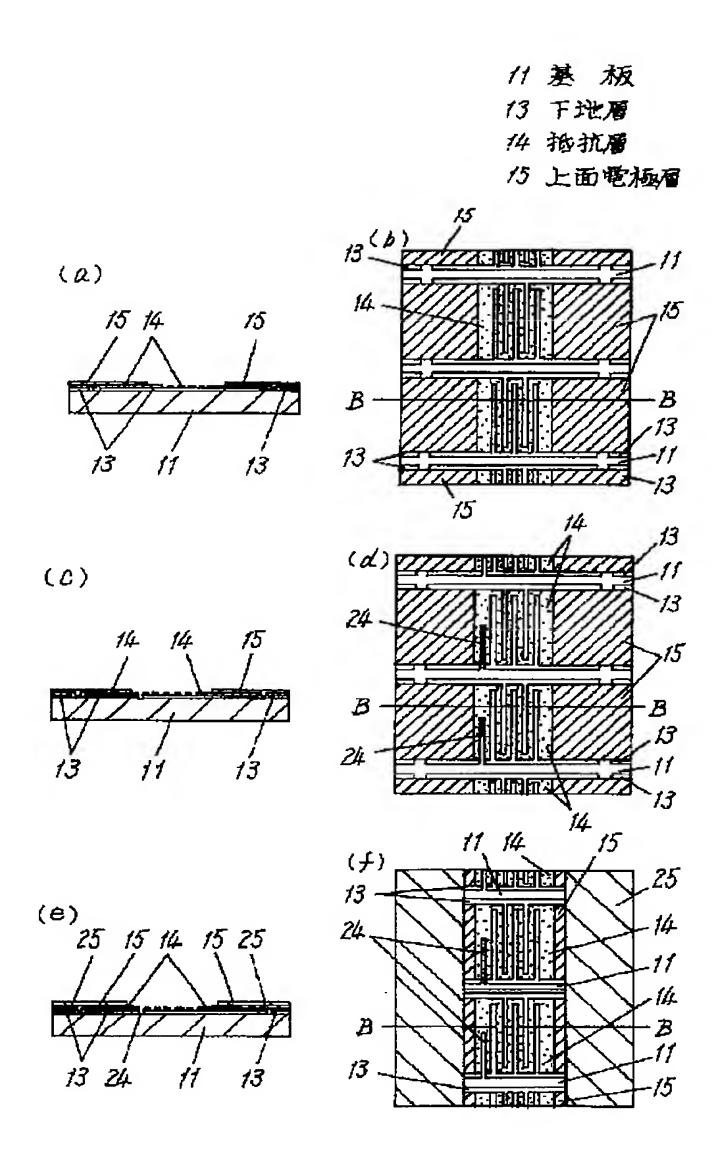
# [Drawing 2]



[Drawing 3]



[Drawing 4]

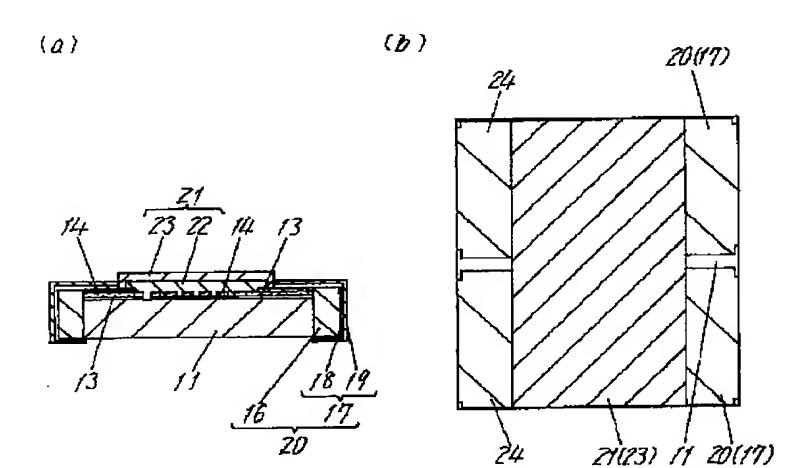


[Drawing 8]

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11 基 板 17 めっき層
13 下地層 20 外部電極層
44 抵抗層 21 保護膜
15 上面電極層 22 第 1 の保護層

16 端面電極層 23 第2の保護層



# [Drawing 9]

11 基板 20 外部電極層

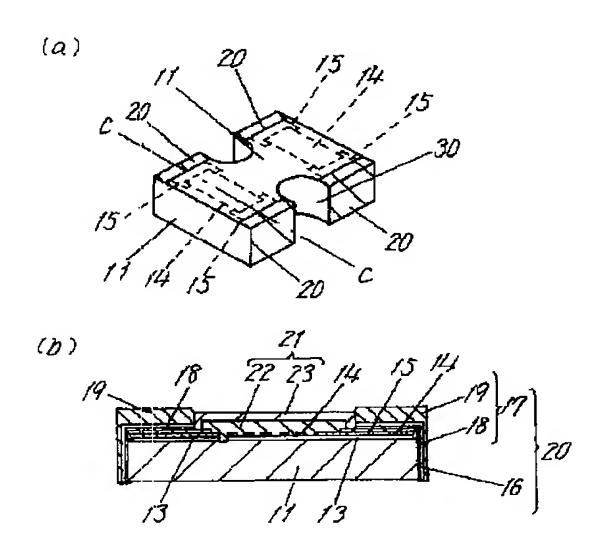
13 下地層 21 保護膜

14 抵抗層 22 第10保護層

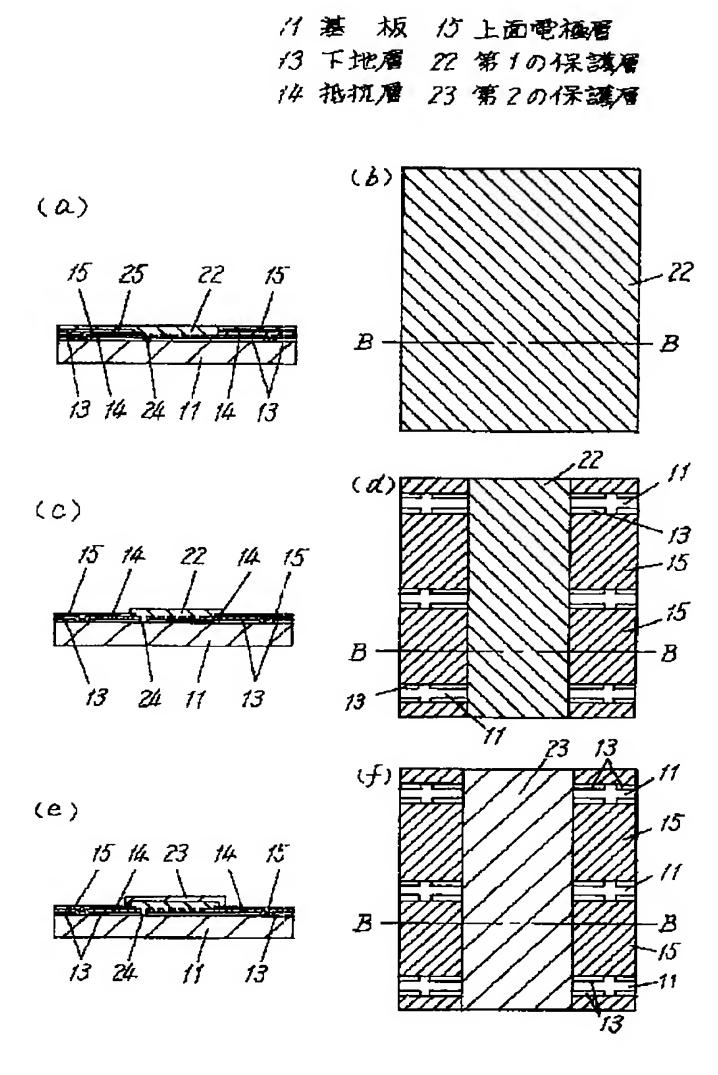
15 上面電極層 23 第20保護層

16 端面電極層 30 凹 部

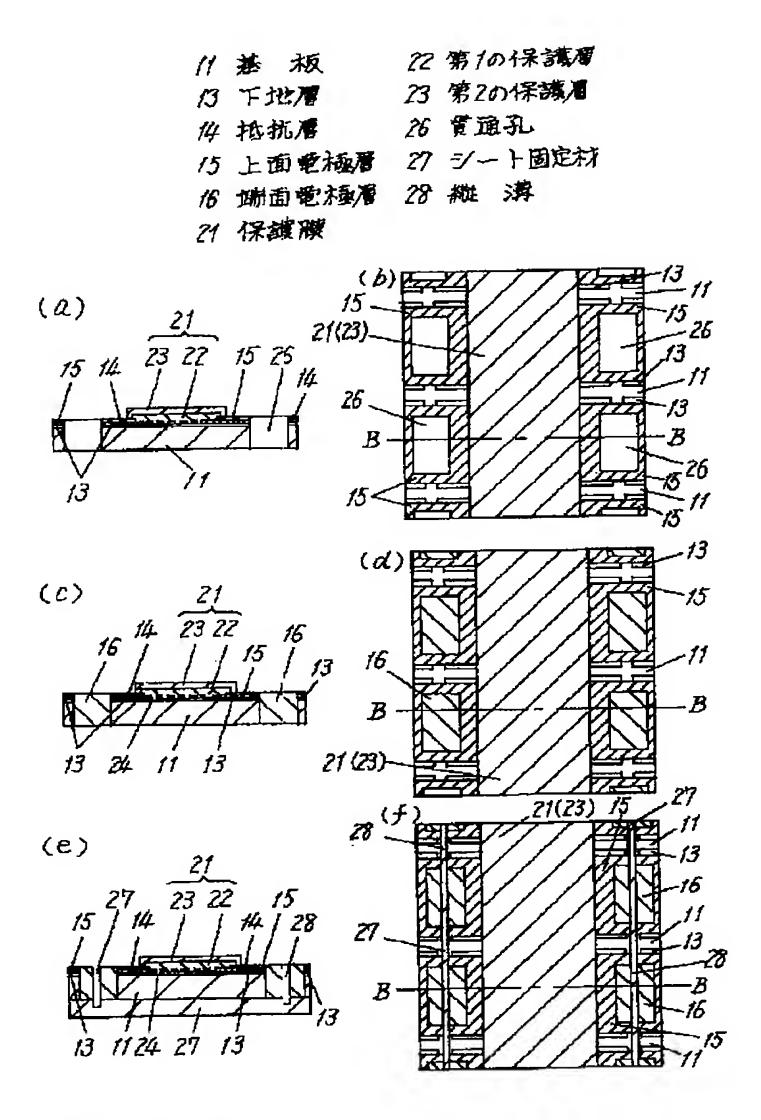
17 めっき層



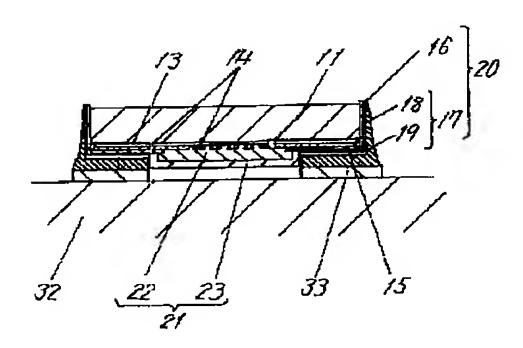
[Drawing 5]



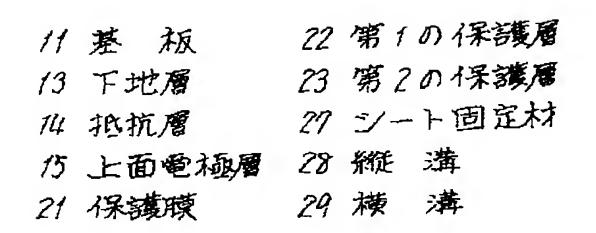
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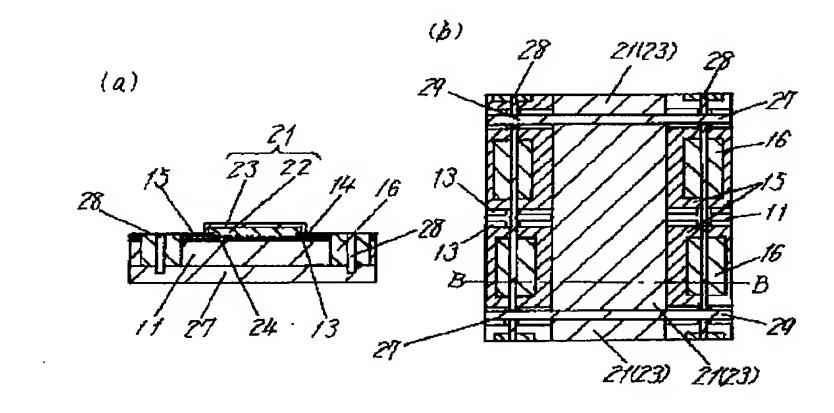


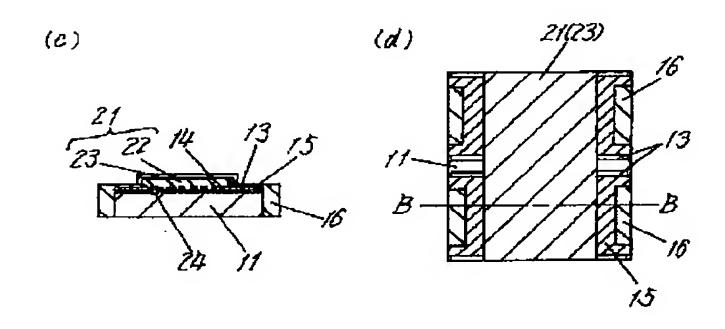
[Drawing 17]



[Drawing 7]

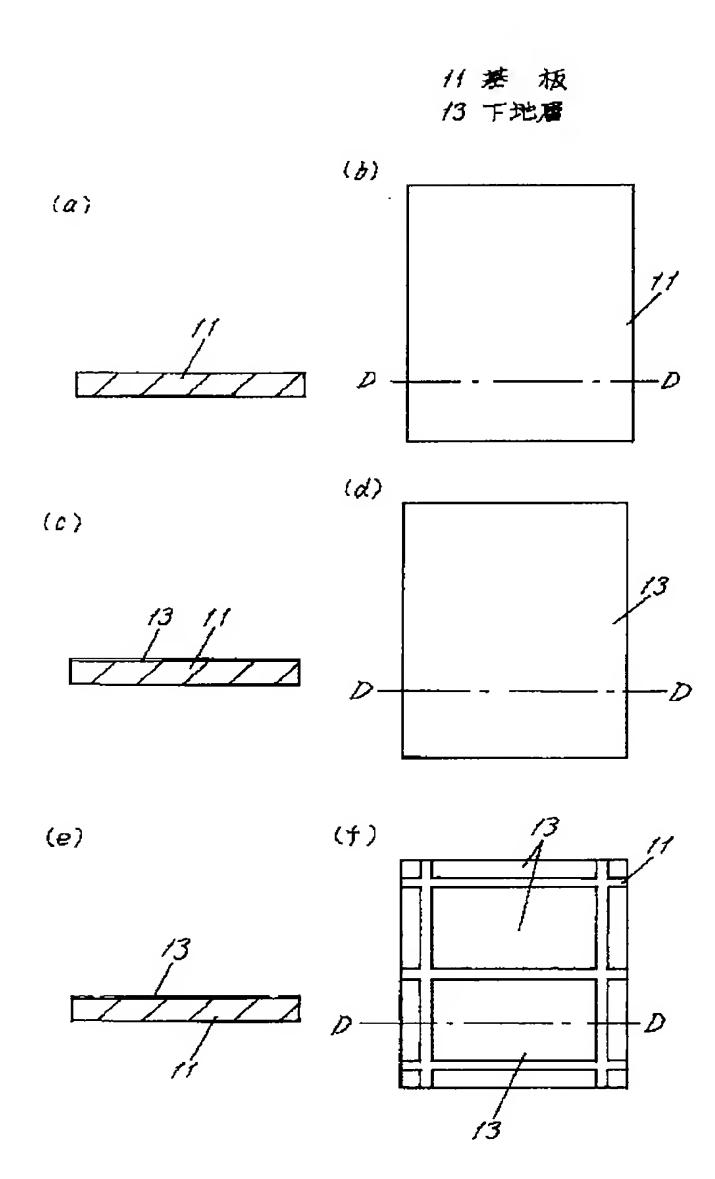






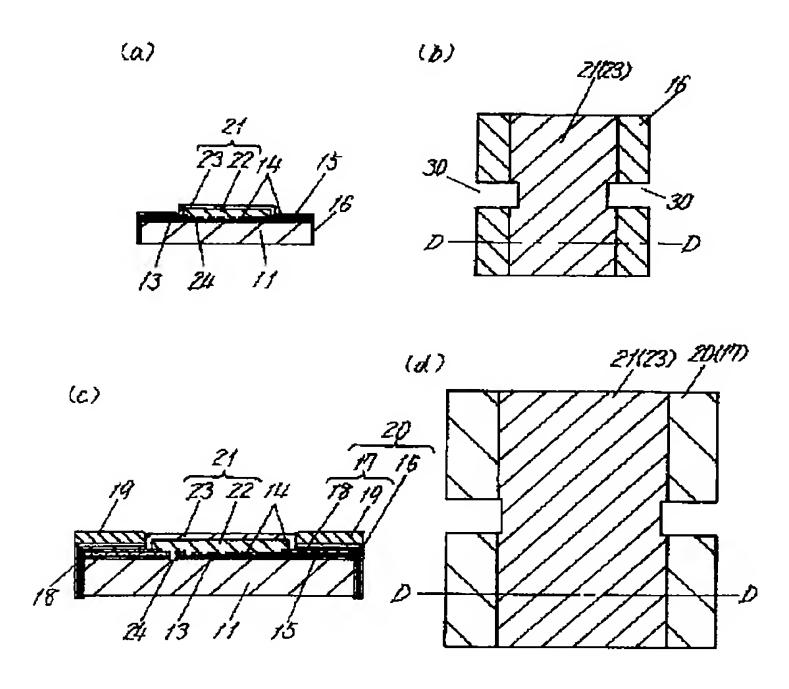
[Drawing 10]

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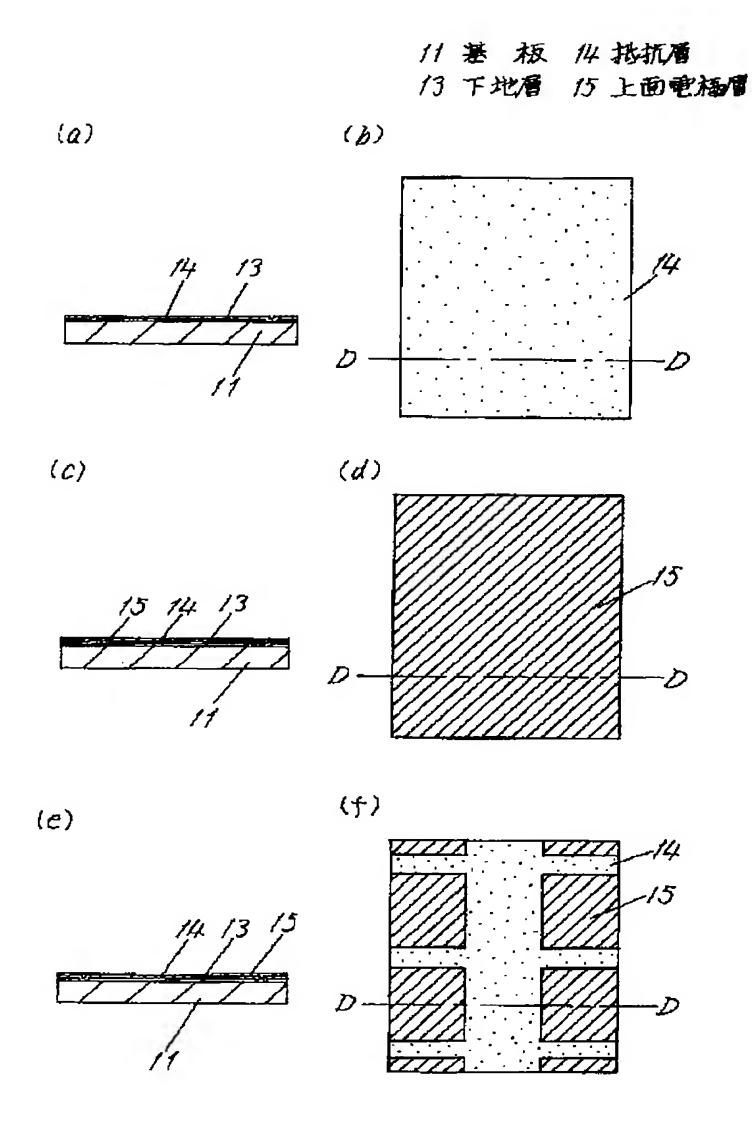
[Drawing 16]

17 基 板 17 めっき層 13 下地層 20 外部電極層 14 抵抗層 21 保護膜 15 上面電極層 22 第 1 の保護層 16 端面電極層 23 第 2 の保護層

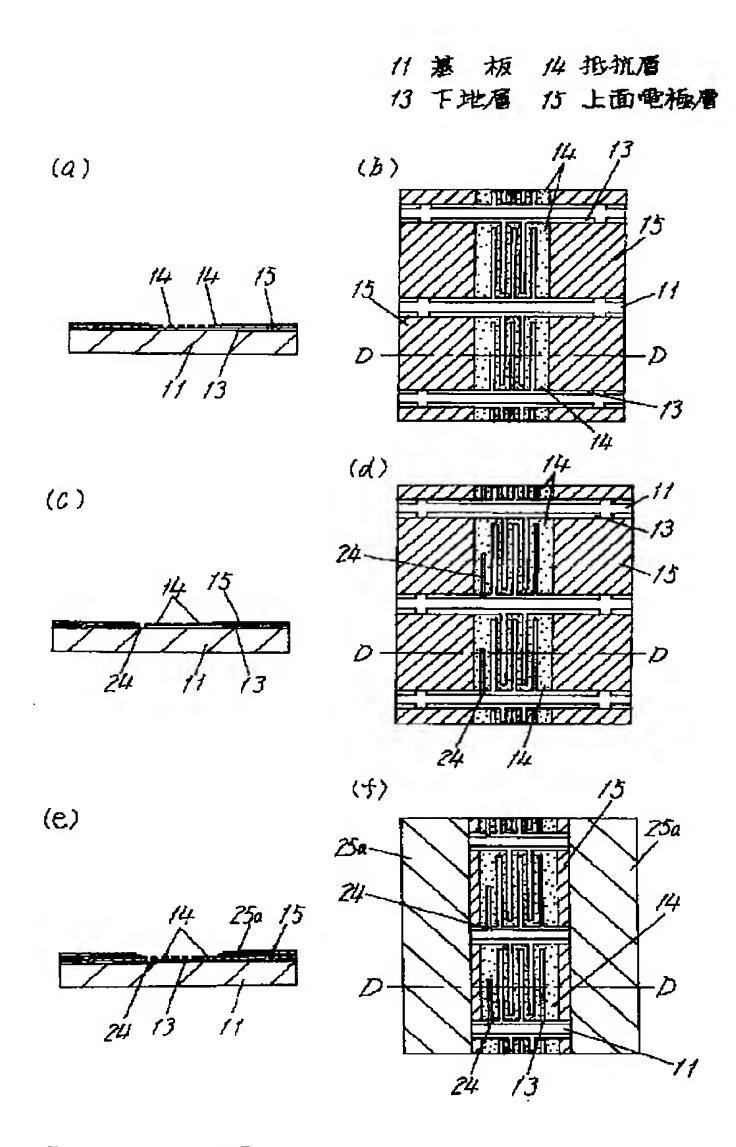


[Drawing 11]

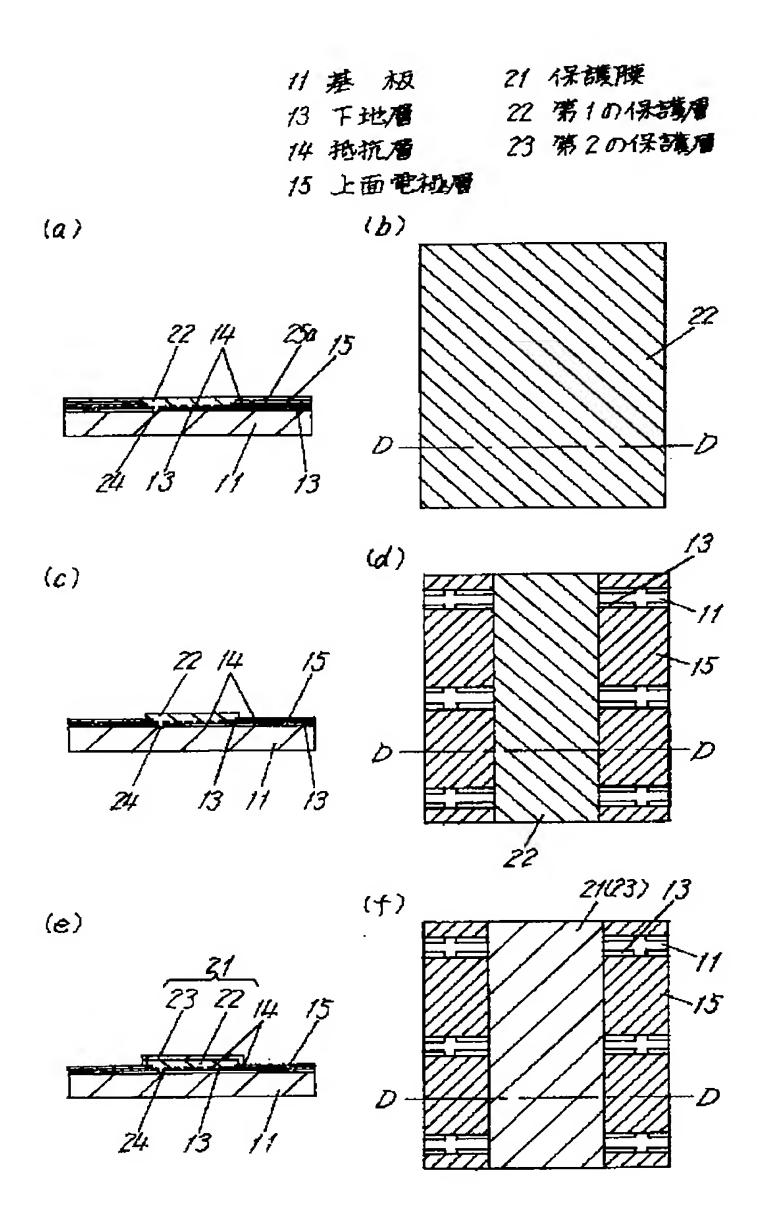
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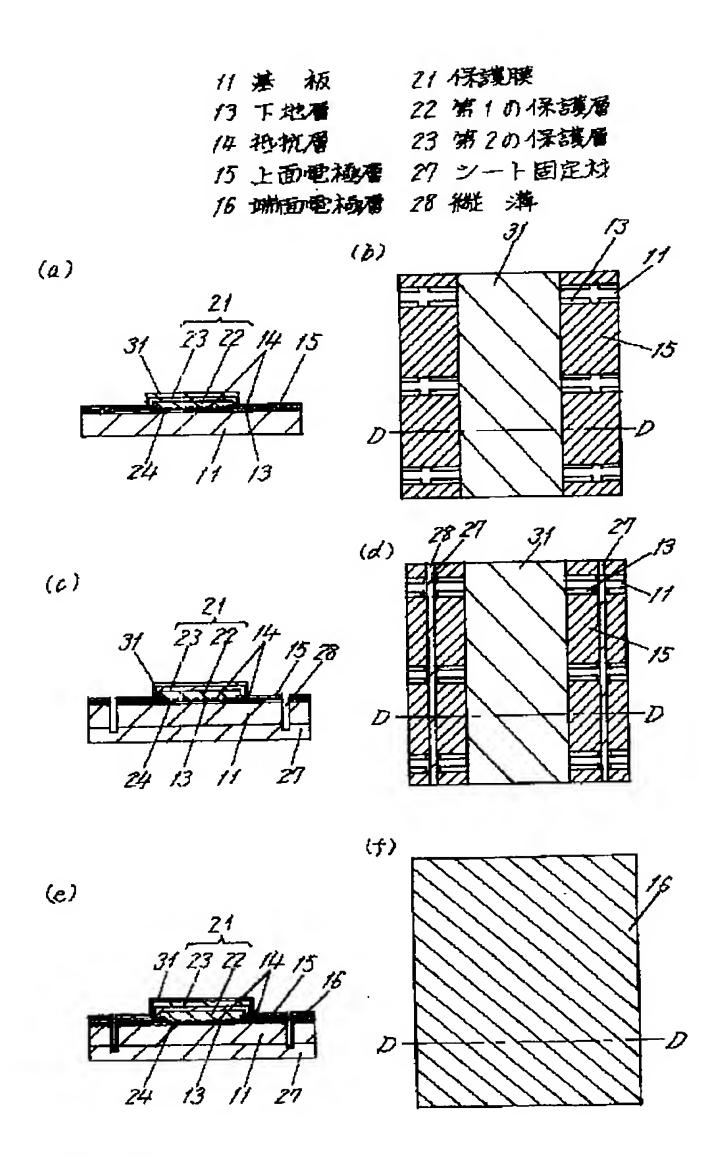
[Drawing 12]



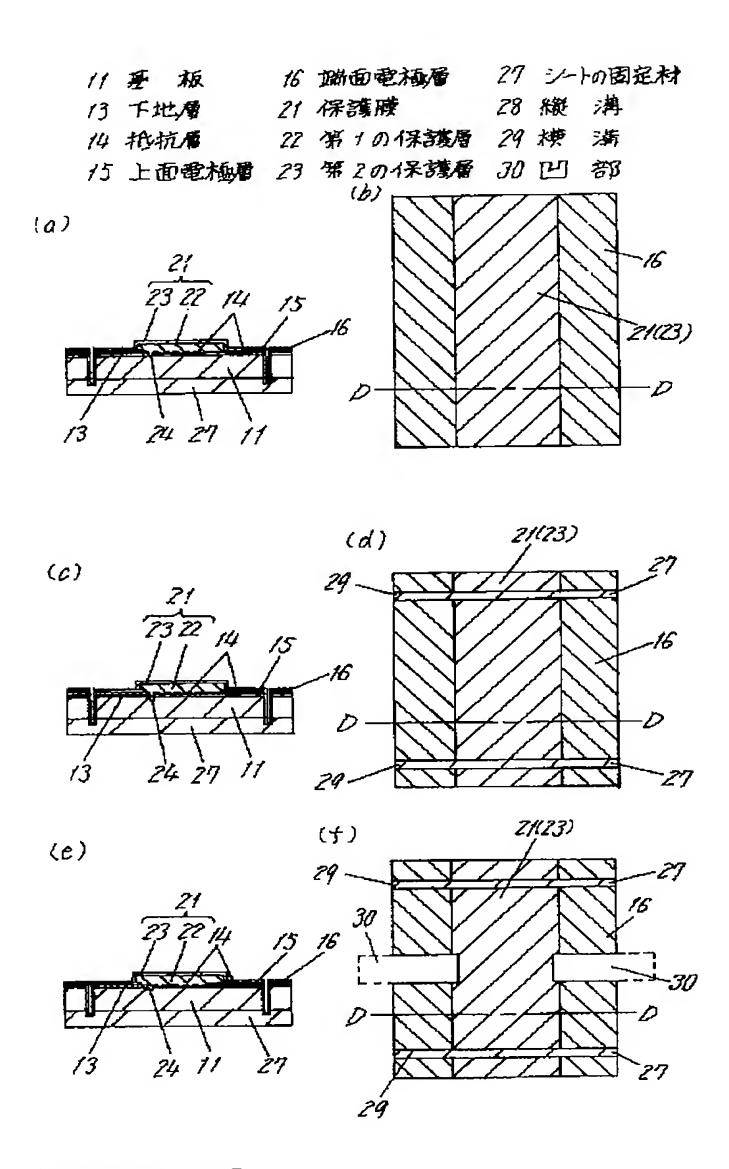
[Drawing 13]



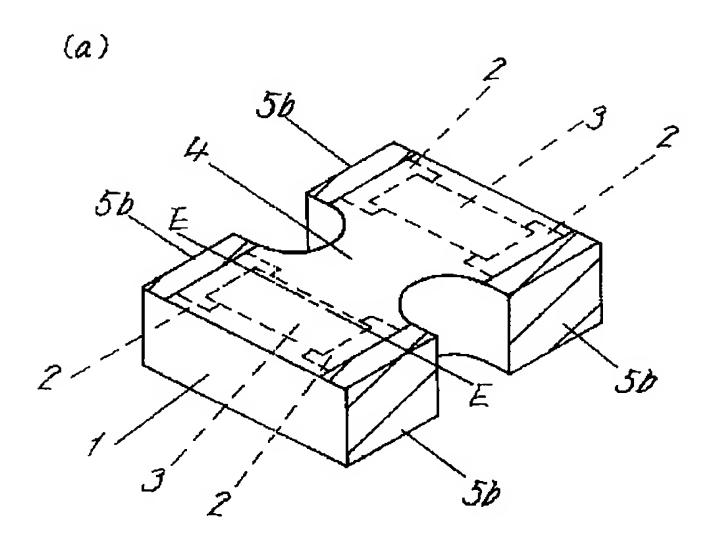
[Drawing 14]

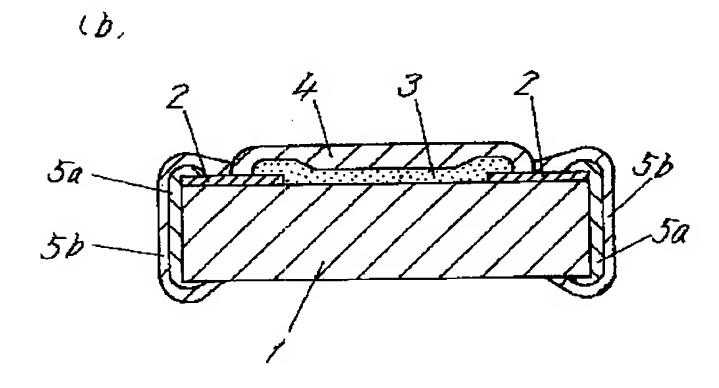


[Drawing 15]



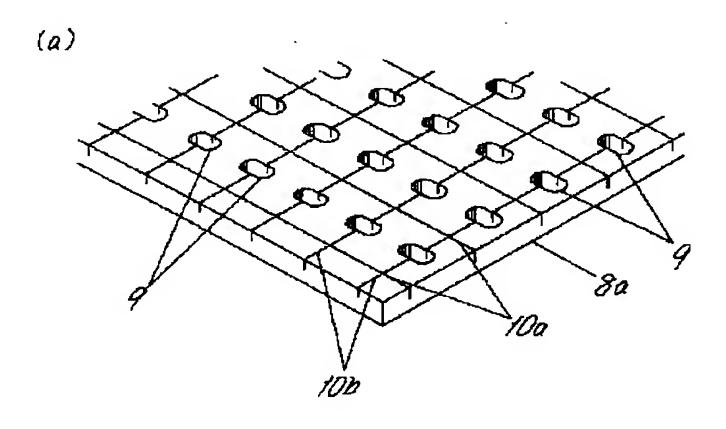
[Drawing 18]

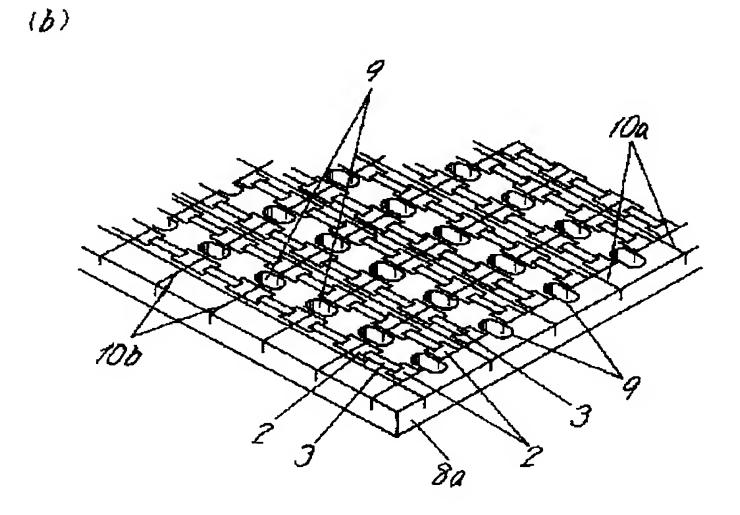




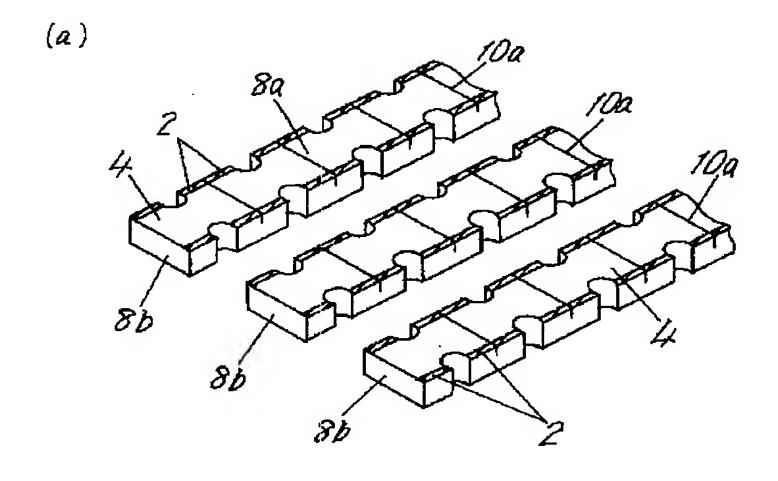
[Drawing 19]

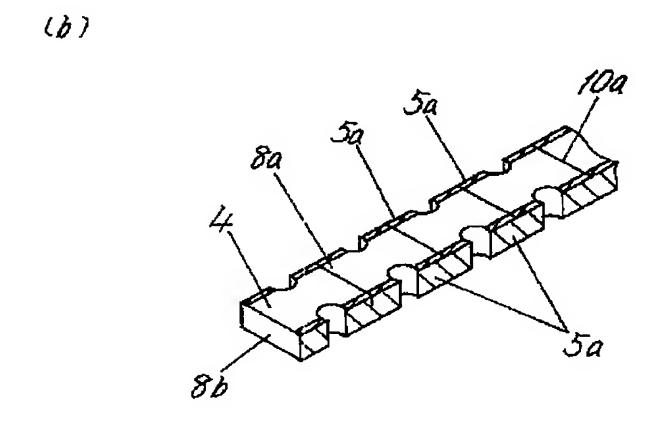
17/19





[Drawing 20]





[Translation done.]

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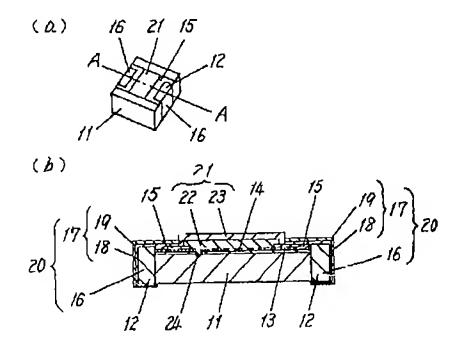
### (54) 【発明の名称】 抵抗器およびその製造方法

#### (57)【要約】

【課題】 基板の切断コストを抑えることができる抵抗 器およびその製造方法を提供することを目的とする。

【解決手段】 基板11と、前記基板11の上面に設けられた抵抗層14と、前記抵抗層14の上面の両端部に設けられた一対の上面電極層15とを有し、前記基板11は樹脂系の材料からなることを特徴とするものである。

- 11 基 板
- 12 切り欠き部
- 13 下地層
- 4 抵抗層
- 15 上面電極層
- 16 端面電極層
- りめっき層
- 20 外部電極層
- 21 保護膜
- 27 第107保護層
- 23 第2の保護層



#### 【特許請求の範囲】

【請求項1】 基板と、前記基板の上面に設けられた抵抗層と、前記抵抗層の上面の両端部に設けられた一対の上面電極層とを有し、前記基板は樹脂系の材料からなることを特徴とする抵抗器。

【請求項2】 抵抗層を基板の上面に設けられた酸化物からなる下地層の上面に形成したことを特徴とする請求項1記載の抵抗器。

【請求項3】 基板が液晶ポリマーからなることを特徴とする請求項1記載の抵抗器。

【請求項4】 一対の上面電極層と電気的に接続されるように前記基板の端面に設けられた一対の端面電極層および前記端面電極層の表面に形成されためっき層からなる外部電極層を、前記基板の両端部に設けられた一対の切り欠き部に形成したことを特徴とする請求項1記載の抵抗器。

【請求項5】 端面電極層を金属粉末と樹脂とからなる 材料で構成したことを特徴とする請求項4記載の抵抗 器。

【請求項6】 外部電極層の上面を保護膜の上面の上方に設けたことを特徴とする請求項4記載の抵抗器。

【請求項7】 外部電極層を基板の裏面に設けないよう にしたことを特徴とする請求項4記載の抵抗器。

【請求項8】 外部電極層を上面電極層の上面に設けた ことを特徴とする請求項4記載の抵抗器。

【請求項9】 少なくとも抵抗層を覆うように設けられた保護膜が酸化物からなる第1の保護層と、前記第1の保護層の上面に形成された樹脂からなる第2の保護層とで構成されたことを特徴とする請求項1記載の抵抗器。

【請求項10】 基板と、前記基板の上面に設けられた複数の抵抗層と、前記複数の抵抗層のそれぞれの上面の両端部に設けられた複数対の上面電極層と、前記複数対の上面電極層と電気的に接続されるように前記基板の端面に設けられた複数対の端面電極層および前記端面電極層の表面に形成されためっき層からなる複数の外部電極層と、前記基板は樹脂系の材料からなり、前記基板の端面における前記外部電極層間に位置する部分に凹部が形成されたことを特徴とする抵抗器。

【請求項11】 樹脂系の材料からなる基板に酸化物からなる下地層を設ける工程と、前記下地層の上面に抵抗層を設ける工程と、前記一対の上面電極層と電気的に接続されるように、前記基板の端面に形成される一対の端面電極層を設ける工程と、前記一対の端面電極層を設ける工程と、前記一対の端面電極層を設ける工程と、前記一対の端面電極層を設けて外部電極層を形成する工程と、少なくとも前記抵抗層を覆うように保護膜を設ける工程とを備えたことを特徴とする抵抗器の製造方法。

【請求項12】 端面電極層を金属粉末と樹脂とからなる混合ペーストを硬化させることにより形成するようにしたことを特徴とする請求項11記載の抵抗器の製造方

法。

【請求項13】 上面電極層および抵抗層をスパッタにより形成した後に、それぞれフォトリソ工法により所定形状にパターンニングすることを特徴とする請求項11記載の抵抗器の製造方法。

【請求項14】 下地層および保護膜はスパッタにより 形成されたことを特徴とする請求項11記載の抵抗器の 製造方法。

【請求項15】 樹脂系の材料からなる基板に下地層を設ける工程と、前記複数の抵抗層の上面に複数の抵抗層を設ける工程と、前記複数の抵抗層の上面の両端部に複数対の上面電極層を設ける工程と、前記複数対の上面電極層と電気的に接続されるように、前記基板の端面に形成される複数対の端面電極層、および前記端面電極層の表面にめっき層を設けて外部電極層を形成する工程と、少なくとも前記複数の抵抗層を覆うように保護膜を設ける工程とを備え、前記基板の端面における前記外部電極層間に位置する部分に凹部を形成することを特徴とする抵抗器の製造方法。

【請求項16】 少なくとも保護膜を設けた後、1個の抵抗器に相当する領域が連続して区画されるように分割用の縦溝と横溝とを基板に設け、前記分割用の縦溝と横溝に沿って前記基板を分割し、複数の抵抗器を得るようにしたことを特徴とする請求項11または15記載の抵抗器の製造方法。

【請求項17】 分割用の縦溝と横溝をレーザーにより 形成することを特徴とする請求項16記載の抵抗器の製 造方法。

【請求項18】 基板の縦溝となる部分を跨がり、かつ 横溝を跨がらないように貫通孔を設け、前記貫通孔に導 電体を充填させるとともに前記導電体を上面電極層と電 気的に接続させて端面電極層を設けるようにしたことを 特徴とする請求項16記載の抵抗器の製造方法。

【請求項20】 分割用の縦溝あるいは横溝に、端面電極層をスパッタにより形成したことを特徴とする請求項16記載の抵抗器の製造方法。

【請求項21】 基板にシート固定材を貼り付けた後、 分割用の縦溝と横溝とを基板に設け、その後、基板から 前記シート固定材を分離させるようにして基板を分割す ることを特徴とする請求項16記載の抵抗器の製造方 法。

【請求項22】 シート固定材として紫外線硬化特性を 有する接着剤を含むものを用いたことを特徴とする請求 項21記載の抵抗器の製造方法。

【請求項23】 基原からシート固定材を分離させる工程は紫外線を照射することにより行うことを特徴とする

請求項22記載の抵抗器の製造方法。

【発明の詳細な説明】

[0001]

【発明の属する技術分野】本発明は、各種電子機器に使用される抵抗器、あるいは微細にパターン形成された多連チップ抵抗器およびその製造方法に関するものである。

### [0002]

【従来の技術】近年、電子機器の小形化に伴い、プリント基板への実装密度を上げるために、電子機器に使用される抵抗器などの電子部品に対して、小形化や複数の独立素子が1つのユニットになっている多連化の要求が高まってきている。

【0003】従来の抵抗器として、実開平4-3800 1号のマイクロフィルタに記載されたものが知られている。

【0004】なお、ここでは抵抗器として、抵抗器のうちの1つである複数の独立した抵抗層が1つのユニットになっている多連チップ抵抗器について述べる。

【 O O O 5 】以下、従来の抵抗器およびその製造方法について、図面を参照しながら説明する。

【0006】図18(a)は従来の抵抗器の斜視図、図18(b)は同E-E線断面図である。

【0007】図18において、1はアルミナからなる絶縁基板である。2は絶縁基板1の上面の両端部に設けられた二対の上面電極層である。3は二対の上面電極層2に一部が重なるように設けられた2つの抵抗層である。このとき2つの抵抗層3は独立している。4は2つの抵抗層3の全体を覆うように設けられた保護層である。5 は絶縁基板1の側面に設けられた二対の側面電極層である。5 りは二対の上面電極層2および二対の側面電極層5 a の表面に設けられたニッケルとはんだめっきからなるめっき層である。

【0008】以上のように構成された従来の抵抗器について、以下にその製造方法を図面を参照しながら説明する。

【0009】図19、図20は従来の抵抗器の製造方法を示す工程図である。

【0010】まず、図19(a)に従来の抵抗器を製造する場合のシート状の絶縁基板8aを示す。この絶縁基板8aにはスルーホール9および縦方向の分割溝10aおよび横方向の分割溝10bが形成されている。

【0011】次に、図19(b)に示すように、シート 状の絶縁基板8aの上面に、複数対の上面電極層2を印 刷形成し、更にそれぞれの対の上面電極層2の一部に重 なるように複数の抵抗層3を印刷形成する。

【0012】次に、図20(a)に示すように、複数の抵抗層3の全体を覆うように複数の保護層4を印刷形成した後、横方向の分割溝10b(図18に図示)に沿って分割し、短冊状の絶縁基板8bに分割する。

【0013】次に、図20(b)に示すように、短冊状の絶縁基板8bの側面部に側面電極層5aを塗着形成する。

【0014】その後、短冊状の絶縁基板8bを縦方向の分割溝10aに沿って分割し、個片状の絶縁基板(図示せず)を得る。

【0015】最後に、図18(a)に示すように上面電極層2および側面電極層5aの表面にニッケルめっきを施した後、はんだめっきを施すことにより、めっき層5bを形成し、従来の抵抗器を製造していた。

【0016】また、前記抵抗器も非常に小形化されてきており、近年では長さ0.6mm×幅0.8mm×厚み0.35mmに2素子を内蔵した非常に小形な多連形の抵抗器も製造されるようになってきた。

#### [0017]

【発明が解決しようとする課題】上記従来の抵抗器は、 基板1としてアルミナなどの磁器を焼成したものを用い ているため、基板の組成バラツキや焼成時の温度バラツ キによって、基板に寸法バラツキが生じていた(この寸 法バラツキは、約100mm×約100mmの基板では 約0.5mm程度に達する)。

【0018】この寸法バラツキをもつ基板を用いて、抵抗器を製造する場合は、スクリーン印刷に使用するマスクを多数用意し、基板の寸法バラツキに応じてマスクを交換する必要が生じて、非常に工程が煩雑になっていた。

【0019】すなわち、寸法バラツキをもつ基板に対し て上面電極層2、抵抗層3、保護層4などを形成するた めのスクリーン印刷に使用するマスクが少しでもずれる と形成位置がずれて不良となってしまうため、寸法バラ ツキをもつ基板を細かい寸法ランクに分類し、それぞれ の寸法ランクに担当する上面電極層2、抵抗層3、保護 層4などのスクリーン印刷に使用するマスクが必要とな るからである (大法ランクを縦方向、横方向それぞれ) 0.05mm刻みで分類する場合は約600ランク以上 の寸法分類が必要であった)。また、特に多連チップ抵 抗器は、1つのユニットに複数の独立した抵抗層をもつ ため、上面電極層、抵抗層、保護層が非常に微細なパタ ーン形状となり、このことは非常に大きな問題となる。 【0020】さらに、上記した工程の煩雑さを解消する ために、上面電量冒、抵抗層、保護層などのスクリーン 印刷後に基板を共享には、悲板を寸法ランクに分類す る必要が無くなる。この切断を半導体のシリコンウエ ハーを切断するように、ダイアモンドを含有する刃を用 いて行えば、半時はカシリコンウエハーよりアルミナが 硬いため、分割すっための刃の摩耗が非常に早く、この 結果、この方法においては切断コストが多大になるとい う課題を有していて。

【 0 0 2 1 】本発明は、上記従来の課題を解決するもので、基板の切断コストを抑えることができる抵抗器およ

びその製造方法を提供することを目的とする。

#### [0022]

【課題を解決するための手段】上記目的を達成するために本発明の抵抗器は、基板と、前記基板の上面に設けられた抵抗層と、前記抵抗層の上面の両端部に設けられた一対の上面電極層とを有し、前記基板は樹脂系の材料からなることを特徴とするもので、この構成によれば、基板の切断コストを抑えることができるという効果が得られる。

#### [0023]

【発明の実施の形態】本発明の請求項1に記載の発明は、基板と、前記基板の上面に設けられた抵抗層と、前記抵抗層の上面の両端部に設けられた一対の上面電極層とを有し、前記基板は樹脂系の材料からなることを特徴とするもので、この構成によれば、アルミナより柔らかい樹脂系の材料からなる基板を用いたため、基板切断用の刃の摩耗を抑えることができ、これにより、基板の切断コストを抑えることができるという作用を有するものである。

【0024】請求項2に記載の発明は、抵抗層を基板の上面に設けられた酸化物からなる下地層の上面に形成したことを特徴とするもので、この構成によれば、一般的に吸湿性のある樹脂系の材料からなる基板上面に酸化物からなる下地層を形成したため、酸化物からなる下地層によって水分の基板への侵入を減少させることができ、これにより、基板の耐湿性が向上するという作用を有するものである。

【0025】請求項3に記載の発明は、基板が液晶ポリマーからなることを特徴とするもので、この構成によれば、基板の熱膨張係数が容易に選択できるため、抵抗層やプリント基板の熱膨張係数との関係を調整でき、これにより、熱膨張係数の違いによる使用時における基板の反りなどを防止できるという作用を有するものである。【0026】請求項4に記載の発明は、一対の上面電極層と電気的に接続されるように前記基板の端面に設けられた一対の端面電極層および前記端面電極層の表面に形成されためっき層からなる外部電極層を、基板の両端部に設けられた一対の切り欠き部に形成したことを特徴とするもので、この構成によれば、切り欠き部のない基板に端面電極層を設けたものよりも、端面電極層が基板から突出しない分だけ端面電極層を含めた抵抗器を小形化

【0027】請求項5に記載の発明は、端面電極層を金属粉末と樹脂からなる材料で構成したことを特徴とするもので、この構成によれば、端面電極層を130℃~240℃という低温で焼成できるため、抵抗層への熱の影響を抑えることができ、これにより、生産中における抵抗値の変化を小さくできるという作用を有するものである。

にできるという作用を有するものである。

【0028】請求項6に記載の発明は、外部電極層の上

面を保護膜の上面より上方に設けたことを特徴とするもので、この構成によれば、基板の上面側をプリント基板側に向けても外部電極の上面がプリント基板に接触するため、基板の上下面のどちらをプリント基板側に向けても実装可能になるという作用を有するものである。

【0029】請求項7に記載の発明は、外部電極層を基板の裏面に設けないようにしたことを特徴とするもので、この構成によれば、基板の裏面を自動実装機の吸着ピンで吸着し、基板の上面側をプリント基板側に向けてプリント基板に集造する場合、吸着時の安定性が向上するため、高い実装率を確保できるという作用を有するものである。

【0030】請定項8に記載の発明は、外部電極層を上面電極層の上面に設けたことを特徴とするもので、この構成によれば、外部電極層と上面電極層との接触面積が大きくなるため、熱調整などの環境負荷を受けてもこの間の接触抵抗の場別を抑えることができ、これにより、抵抗層が低抵抗性でも抵抗層の抵抗値に対する接触抵抗の増加分の割合せることできるため、抵抗値変化率を低くできるという得用を有するものである。

【0031】請注準)に記載の発明は、少なくとも抵抗層を覆うように設けられた保護膜が酸化物からなる第1の保護層と、前記事1の保護層の上面に形成された樹脂からなる第2の信息性とで構成されたことを特徴とするもので、この構成によれば、耐熱性の優れた酸化物からなる第1の保護層とで抵抗。可湿性に優れた樹脂からなる第2の保護層とで抵抗。「可湿力れるため、抵抗層が熱や水分の影響を受けず、「れたより、使用時の抵抗値変化率を小さくできると、「作用を有するものである。

【0032】請立門上のに記載の発明は、基板と、前記 基板の上面に設けられた自数の抵抗層と、前記複数の抵 抗層のそれぞれから同の同盟部に設けられた複数対の上 面電極層と、前点「二人特の上面電極層と電気的に接続さ れるように前記書(の端面に設けられた複数対の端面電 極層および前記の三章極層の表面に形成されためっき層 からなる複数の外部高極層と、少なくとも前記複数の抵 抗層を覆うように言いられた保護膜とを有し、前記基板 は樹脂系の材料が立まり、前記基板の端面における前記 外部電極層間に任当する部分に凹部が形成されたことを 特徴とするもので、こに構造によれば、アルミナより柔 らかい樹脂系の背景が立なる悲板を用いたため、基板切 断用の刃の摩耗・ニールることができ、これにより、基板 の切断コストを自己したものできることに加え、複数の 独立した抵抗層・ファス多連チップ抵抗器において、各 抵抗層に対応すること常常に関語間は凹部によって基板の 端面における遺具が発しているため、外部電極層の形成 時に外部電極層同一、接触して抵抗層同士が電気的に接 続してしまうことに出てきるという作用を有するもの である。

【0033】請告ニュコニ記版の発明は、樹脂系の材料

からなる基板に酸化物からなる下地層を設ける工程と、 前記下地層の上面に抵抗層を設ける工程と、前記抵抗層 の上面の両端部に一対の上面電極層を設ける工程と、前 記一対の上面電極層と電気的に接続されるように、前記 基板の端面に形成される一対の端面電極層を設ける工程 と、前記一対の端面電極層の表面にめっき層を設けて外 部電極層を形成する工程と、少なくとも前記抵抗層を覆 うように保護膜を設ける工程とを備えたことを特徴とす るもので、この製造方法によれば、アルミナより柔らか い樹脂系の材料からなる基板を用いたため、基板切断時 における基板切断用の刃の摩耗を抑えることができるとい う作用を有するものである。

【0034】請求項12に記載の発明は、端面電極層を金属粉末と樹脂とからなる混合ペーストを硬化させることにより形成するようにしたことを特徴とするもので、この製造方法によれば、端面電極層130℃~240℃という低温で焼成できるため、抵抗層への熱の影響を抑えることができ、これにより、生産中における抵抗値の変化を小さくできるという作用を有するものである。

【0035】請求項13に記載の発明は、上面電極層および抵抗層をスパッタにより形成した後に、それぞれフォトリソ工法により所定形状にパターンニングすることを特徴とするもので、この製造方法によれば、上面電極層および抵抗層を薄く形成できるため、分割用の縦溝あるいは横溝で基板を分割し易くなることに加え、フォトリソ工程により抵抗層が高精度にパターン形成されるため、抵抗層の有効面積を大きくすることができ、これにより、高電力が印加されても抵抗値変化率を低くできるという作用を有するものである。

【0036】請求項14に記載の発明は、下地層および 保護膜はスパッタにより形成されたことを特徴とするも ので、この製造方法によれば、下地層および保護膜を緻 密に形成できるため、抵抗層へ湿気が入り込みにくくな り、これにより、抵抗層が安定するという作用を有する ものである。

【0037】請求項15に記載の発明は、樹脂系の材料からなる基板に下地層を設ける工程と、前記下地層の上面に複数の抵抗層を設ける工程と、前記複数の抵抗層の上面の両端部に複数対の上面電極層を設ける工程と、前記複数対の上面電極層と電気的に接続されるように、前記基板の端面に形成される複数対の端面電極層、および前記端面電極層の表面にめっき層を設けて外部電極層を形成する工程と、少なくとも前記複数の抵抗層を覆うように保護膜を設ける工程とを備え、前記基板の端面における前記外部電極層間に位置する部分に凹部を形成することを特徴とするもので、この製造方法によれば、アルミナより柔らかい樹脂系の材料からなる基板を用いるため、基板切断用の刃の摩耗を抑えることができることに加まり、基板の切断コストを抑えることができることに加

【0038】請、道・自口記載の発明は、少なくとも保護膜を設けた後、1日の民抗器に相当する領域が連続して区画されるように、割用の縦溝と横溝とを基板に設け、前記分割用の計算と種溝に沿って前記基板を分割し、複数の抵抗器に得るようにしたことを特徴とするもので、この製造生にはよりにしたことを特徴とするもので、この製造生にはよりに上面電極層、抵抗層、端面電極層、保護によりに基板を分割するため、基板を対法ランニュンが生活を関が無くなり、これにより、工程の煩雑には、自己に対してことに加え、基板を端面電極層などを形成により、一回分割するだけで複数の抵抗器を得ることがでは、一回分割するだけで複数の抵抗器を得ることがでは、一回分割するだけで複数の抵抗器を得ることがでは、一回分割するだけで複数の抵抗器を得ることがでは、一回分割するだけで複数の抵抗器を得ることがでは、一回分割するだけで複数の抵抗器を得ることがである。

【0039】請注手「日口記載の発明は、分割用の縦溝 と横溝をレーザーに、り形成することを特徴とするもの で、この製造方法につれば、レーザーの照射された部分 だけ確実かつ高温。一部門の総溝と横溝を形成できるた め、生産性が向けていという信用を有するものである。 【0040】請申自らに制度の発明は、基板の縦溝と なる部分を跨がサービー 福温と跨がらないように貫通孔 を設け、前記買いりでは、本本を充填させるとともに前記 導電体を上面電子に電気的に接続させて端面電極層を 設けるようにレーニークリスとするもので、この製造方 法によれば、経済・ (国際) まれた1個の抵抗器に相当 状に分割した後に自己自己自己設けたものよりも、端面 電極層が基板かつ、出しない方だけ端面電極層を含めた 抵抗器を小形化できるという同用を有するものである。 【0041】計一日(自計)の発明は、基板の縦溝と ニュー ag 1世帯がらないように貫通孔 なる部分を跨が を設け、前記買りは、「日沼をスパッタにより形成 したことを特能して、この製造方法によれば、 2000年 売売器に相当する領域内に 縦溝と横溝に国 端面電極層を形する。これでも生板を個片状に分割した 後に端面電極層が基板 から突出しない。これは関層を含めた抵抗器を小形 化にできることに、これに薄く端面電極を形成でき るため、貫通清に電信に準用電極層が入り込み、これ により、安定し、『面理問題日上設けることができるとい

【0042】語。三二0三記間の発明は、分割用の縦溝あるいは横溝に、三温性にはスパッタにより形成したことを特徴とす。 ココーロの製造方法によれば、非常に薄く端面電影 「カニコーなめ、分割溝内に確実に

う作用を有する こうごご

端面電極層が入り込み、これにより、安定して端面電極層を設けることができるという作用を有するものである。

【0043】請求項21に記載の発明は、基板にシート 固定材を貼り付けた後、分割用の縦溝と横溝とを基板に 設け、その後、基板から前記シート固定材を分離させる ようにして基板を分割することを特徴とするもので、こ の製造方法によれば、分割用の縦溝と横溝のうち一方を 設けたときに位置ずれを起こしてもう一方の分割用の溝 を所定の位置に設けることができなかったり、基板を分 割した時に、個片状の各抵抗器がばらばらに散らばっ て、この後の工程が煩雑になることを防止できるという 作用を有するものである。

【0044】請求項22に記載の発明は、シート固定材として紫外線硬化特性を有する接着剤を含むものを用いたことを特徴とするもので、この製造方法によれば、紫外線を照射することによって高速でシート固定材の接着力を無くすことができるため、生産性が向上することに加え、シート固定材の接着力を根本的に無くすことができるため、基板から確実にシート固定材を分離できるという作用を有するものである。

【0045】請求項23に記載の発明は、基板からシート固定材を分離させる工程は紫外線を照射することにより行うことを特徴とするもので、この製造方法によれば、紫外線を照射することによって容易にシート固定材の接着力を無くすことができるため、容易に基板からシート固定材を分離できるという作用を有するものである。

【0046】(実施の形態1)以下、実施の形態1における抵抗器およびその製造方法について、図面を参照しながら説明する。

【0047】図1(a)は本発明の実施の形態1における抵抗器の斜視図、図1(b)は同A-A線断面図である。なお、図1(a)は、後述するめっき層17を省略している。

【0048】図1(a)(b)において、11は基板で、両端部に切り欠き部12を有し、樹脂、樹脂化合物、樹脂混合物などの樹脂系の材料からなる。この切り欠き部12の形状は、基板11の上方から見て、略矩形状となっている。もちろん略半円形状などの他の形状であっても構わない。13は下地層で、基板11の上面に設けられ、アルミナを主成分とする酸化物からなる。14は抵抗層で、基板11上面に下地層13を介して設けられている。抵抗層14の材料は、目標とする抵抗値や用途などによって、酸化ルテニウムやニッケルーリンなどから選定すればよい。

【0049】なお、基板11として、液晶ポリマーを用いると、熱膨張係数の異なる液晶ポリマーのうち、適当な熱膨張係数のものを容易に選択できるため、抵抗層14やプリント基板の熱膨張係数との関係を調整でき、こ

れにより、熱調が「ハー」による使用時における基板 11の反りなどでで出てかっという効果が得られる。また、下地層13/10/2012では最大とする酸化物は、水 分の基板11へにはなったさせることができるため、 一般的に吸湿性には、10/2012ではあるとができるため、 からなる基板110でに温性を向上させる効果を得るためである。

【0050】1日は一世に上面電極層で、抵抗層14の上面の両端部に高いた。会系の材料からなる。16は一対の端面電極に、近点は、上面電極層15のそれぞれの端面と同じにはに対応されるように、基板11の両端部に設けられて、近点には、近点で成され、導電体からなる。このは、は、一定に対応され、導電体からなる。このは、は、一定に対応される場所を知れば、、第二十を130℃~240℃という低温で焼成では、一定に対応的への熱の影響を抑えることができ、このは、流流的への熱の影響を抑えることができ、このは、流流的への熱の影響を抑えることができ、このは、流流的への熱の影響を抑えることができ、このは、流流的への熱の影響を抑えることができる。

【0051】このように関節電極層16を基板11の両端部に設けられたに見た。部12に形成することによって、切り欠き部には、事業に関節電極層を設けたものよりも、端面電性には、14により、上から突出しない分だけ端面電極層16に、アイルにをるという効果が得られる。これでは返雇16は切り欠き部12全体を埋める。エアのしなでおり、この結果、外部電極層の断面量に、「からため、プリント基板との接合強度を向上に、アラミな。

3とで構成することによって、耐熱性、耐湿性に優れた 保護膜21で抵抗層14が覆われるため、抵抗層14が 熱や水分の影響を受けなくて済み、これにより、使用時 の抵抗値変化率を小さくできるという効果も得られる。 さらに、外部電極層16を上面電極層15の上面に設け ることによって、外部電極層20と上面電極層15との 接触面積が大きくなるため、熱衝撃などの環境負荷を受 けてもこの間の接触抵抗の増加を抑えることができ、こ れにより、抵抗層14が低抵抗値でも抵抗層14の抵抗 値に対する接触抵抗の増加分の割合を小さくできるた め、抵抗値変化率を低くできるという効果も得られる。 【0054】以上のように構成された木発明の実施の形

【0054】以上のように構成された木発明の実施の形態1における抵抗器について、以下にその製造方法を図面を参照しながら説明する。

【0055】図2~図8は、本発明の実施の形態1における抵抗器の製造方法を示す図である。なお、各図において、(b)は上面図、(a)は(b)のB-B線断面図であり、これと同様に(d)(f)が上面図、(c)(e)はそれぞれ(d)(f)のB-B線断面図である。

【0056】まず、図2(a)(b)に示すように、樹脂、樹脂化合物、樹脂混合物などの樹脂系の材料からなる基板11を用意する(なお、この基板11は複数の抵抗器を製造するために、1個の抵抗器より大きなシート状の基板をいう。1個の抵抗器を得るためにはこのシート状の基板を分割する必要がある。)。

【0057】なお、基板11の厚みは0.05mm~0.25mmが望ましい。基板11が0.25mm以下と薄いため基板切断時の刃の摩耗を小さく抑えることができる。ただし、0.05mm以下になると抵抗層14などを形成しにくかったり、基板11自体の取扱いが難しくなる。

【0058】次に、図2(c)(d)に示すように、基板11の上面にアルミナなどの酸化物からなる下地層13を設ける。

【0059】次に、図2(e)(f)に示すように、下 地層13をフォトリソ工程によりパターンニングする。 このとき、1個の抵抗器(1個の独立した抵抗層14を 有する部分)に相当する領域の外周部(後述する分割用 の縦溝28、横溝29が形成される部分)以外を残すようにする。

【0060】次に、図3(a)(b)に示すように、下 地層13と、下地層13が上面にない基板11との上面 に、スパッタにより抵抗層14を設ける。

【0061】次に、図3(c)(d)に示すように、抵抗層14上面の金面にスパッタにより金系の材料からなる上面電極層15を設ける。なお、必要に応じて基板11の裏面に裏面電極を設けてもよい。

【0062】次に、図3(e)(f)に示すように、上面電極層15をフォトリソ工法によりパターンニングす

【0063】次に、日本で、今後に示すように、目標とする抵抗値。またからの要に応じてフォトリソ工程やレーザーなって、中国の主任をパターンニングする。さらに、振り、自由の独立した抵抗層14を100円のように、自由する領域の外周部以外に残っている。このとき、中国のみに形成されるようにする。このとき、中国のとび抵抗層14の上面に形成された上面に対し、一般工程で設ける分割用の縦溝28に跨がり、中の設置29に跨がらないようにする。

【0065】次に 4 3)(d)に示すように、1個の抵抗器()17 ½」 選抗層14を有する部分)に相当する領地。 2 1 70個層15間の抵抗値を調整するためには 177 1 ーザートリミングによりトリミング清イ・ 1 3

【0066】次に「74 」 (f)に示すように、少なくとも抵抗に、 るように、上面電標層15の一部の上面に 「1 」 1 」をスクリーン印刷により設ける。この後 「1 」 7 安定するように150℃、10分の温度ではなする。

【0068】 シュード・コー(d) に示すように、レジスト層25 テール 第1の保護層22をパターンニングする

1の保護層22の上面に樹脂からなる第2の保護層23をスクリーン印刷により設ける。この後第2の保護層23が安定するように180℃、30分の温度で硬化する。このとき、第1の保護層22および第2の保護層23からなる保護膜21が、少なくとも抵抗層14を覆うようにする。

【0071】このように、第2の保護層23をスクリーン印刷により設けることによって、第2の保護層23を安価に形成できる。

【0072】次に、図6(a)(b)に示すように、1個の抵抗器(1個の独立した抵抗層14を有する部分)に相当する領域における基板11の両端部に貫通孔26を設ける。すなわち、貫通孔26が後工程で設ける分割用の縦溝28に跨がり、かつ横溝29に跨がらないようにすればよい。なお、この貫通孔26が図1における切り欠き部12に相当する。

【0073】次に、図6(c)(d)に示すように、貫通孔26に金属粉末と樹脂とからなる混合ベーストを充填して端面電極層16を設ける。この後端面電極層の16が安定するように200℃、30分の温度で硬化する。このとき、端面電極層16は、抵抗層14、上面電極層15のそれぞれの端面と電気的に接続されるように基板11の両端面に設ける。

【0074】このように、基板11の縦溝28となる部分を跨がり、かつ横溝29を跨がらないように貫通孔26を設け、貫通孔26に導電体を充填させるとともに上面電極層15と電気的に接続させて端面電極層16を設けるようにしたことによって、縦溝28と横溝29に囲まれた1個の抵抗器に相当する領域内に端面電極層16を形成できるため、基板11を個片状に分割した後に端面電極層16を設けたものよりも、端面電極層16が基板11から突出しない分だけ端面電極層16を含めた抵抗器を小形化できる。

【0075】さらに、端面電極層16を貫通孔26に金属粉末と樹脂とからなる混合ペーストを硬化させることにより形成したため、端面電極層16を130℃~240℃という低温で焼成でき、これにより、抵抗層14への熱の影響を抑えることができ、生産中における抵抗値の変化を小さくできるという効果が得られる。

【0076】また、上記したように貫通孔26に金属粉末と樹脂とからなる導電体を充填する代わりに、スパッタによって端面電極層16を設けてもよい。このとき、上記した効果に加え、貫通孔26が小さくても、端面電極層16を非常に薄く形成できるため、貫通孔26内に確実に端面電極層16が入り込み、これにより、安定して端面電極層16を設けることができるという効果も期待できる。

【0077】次に、図6(e)(f)に示すように、紫外線硬化特性を有する接着剤が片面に設けられたシート固定材27を、基板11下面の全面に、接着剤が基板1

【0078】次に、7 )(b)に示すように、分割用の横溝27 ) (b)に示すように、分割用の横溝27 が洗涤29に跨がらないようにする。

【0082】なり、「記」とように貫通孔20日金属粉末と樹脂とかなってでは、「記」を設ける代わりに、貫通孔26を形成せている。「記」を設けてもよい、このとっては、「記」を設けてもよい。このとき、非常に尊」が入り込み、これにより、方向に確実に関い、「このとの人り込み、これにより、安定して端面には、「の」にはることができる。

**√** √

【0083】()に、「7(1)(d)に示すように、紫外線を照射して、 18世間17を基板11から分離させ、基板11をかたしるとは、18と横溝29に沿って分割して複数の同時は10時間に分割する。

を分離できる。さらに、基板 1 1 からシート固定材 2 7 を分離させる工程は紫外線を照射することにより行うため、紫外線を照射することによって容易にシート固定材 2 7 の接着力を無くすことができ、これにより、容易に基板 1 1 からシート固定材 2 7 を分離できる。

【0085】最後に、図8(a)(b)に示すように、 端面電極層16の表面および露出している上面電極層1 5の上面に、ニッケルめっき層18と低融点金属めっき 層19からなるめっき層17を設ける。

【0086】上記した本発明の実施の形態1における抵抗器は、アルミナより柔らかい樹脂系の材料からなる基板11を用いたため、基板切断用の刃の摩耗を抑えることができ、これにより、基板の切断コストを抑えることができるという効果が得られる。

【0087】また、上面電極層15、抵抗層14、端面電極層16、保護膜21などの形成後に基板11を分割するため、基板11を寸法ランクに分類する必要が無くなり、これにより、工程の煩雑さが解消するという効果も得られる。

【0088】さらに、上面電極層15、抵抗層14、端面電極層16、保護膜21などの形成後に基板11を分割するため、端面電極層16などを形成するために基板11を一度短冊状に分割する必要はなく、これにより、一回分割するだけで複数の個片状の抵抗器を得ることができ、これにより、工程が簡略化できるという効果も得られる。

【0089】なお、図7、図8においては、横溝29によって独立した個片状の抵抗器(1個の独立した抵抗層14を有する部分)が2個連なったものが複数得られるようになっているが、図1に示したように、横溝29によって1個の独立した抵抗層14を有する抵抗器が複数得られるようにしてもよい。もちろん、上記した効果は、1個の独立した抵抗層を有する抵抗器のような1個の独立した抵抗層を有する抵抗器が2個以上連なったもの(複数の独立した抵抗層が1つのユニットになっている多連チップ抵抗器)のいずれにもいえる。

【0090】(実施の形態2)以下、実施の形態2における抵抗器およびその製造方法について、図面を参照しながら説明する。

【0091】図9(a)は本発明の実施の形態2における抵抗器の斜視図、図9(b)は同C-C線断面図である。なお、図9(a)は、後述する保護膜21を省略している。また、本発明の実施の形態2における抵抗器は、抵抗器の1種である複数の独立した抵抗層が1つのユニットになっている多連チップ抵抗器である。

【0092】図9(a)(b)において、11は基板で、両端部に凹部30を有し、樹脂、樹脂化合物、樹脂混合物などの樹脂系の材料からなる。この凹部30の形状は、基板11の上方から見て、略略半円形状となって

いる。もちろん「アンスト」という形状であっても構わない。13は下アドル 見 1.の上面に設けられ、アルミナを主成分に アールでる。14は巨数の抵抗層で、基板「コニニニニニニニ」3を介して設けられている。抵抗層1/アンドニニニニニニニニンをする抵抗値や用途などによって、酸性にディー、ステーケルーリンなどから選定すればよい。ことには、ほご置14はそれぞれ独立し、かつ互いが ここには、正常されている。

【0093】7.1、 コンとして、液晶ポリマーを用いると、熱力がです。 意音ポリマーのうち、適当な熱膨張係力がです。 空間できるため、抵抗層14やプリント ロン・ シー・ シー・ 空間係を調整でき、これにより、熱サートのデートングにはる使用時における基板11の反りにコンデーという効果が得しれる。また、下地層1 コー・ 主党分とする酸自動は、水分の基板11へのデート、でせることができるため、一般的に吸湿性に、シー・ させる効果を得るためである。

6の表面および、コード、当日16に対応する各上面 電極層15つよう。 つばし、エッケルかっき層 る。また、「おり」は、「自動にはニッケーのっき 層18、エッテー・・・・・・・・・ の表面には低能点金属め っき層15が買い トラー にいば世数の特部電極層 で、各外部に、 (パー 年)別15とめっき増17 とからなり、ルーロー、ローローロ海豚層1下の上面の 一部に形成され、「日」」、「日には設けられていな い。また、宝宝 「名」、基板11の朝面におけ る名外部電子では、ことに対し、自然分に形成でしてい る。2.1 は (計) (1.5 全ての抵抗性) 4 を覆 こりカキどの普で物から うように誤り、 なる第10~27~2 ーールであるい。これポキ シ閲覧からっている。ま - 二の保護署21 第1の た、各類には 保護層21。 1、 こ、 アンゴ2 が形にされてい る。また、石では、「一」、「八八八間膜のでの上面 より上がにはいいない。

【009612。 つまない 時間のを基門は1の裏

面に設けないことによって、基板11の裏面を自動実装 機の吸着ピンで吸着し、基板11の上面側をプリント基 板側に向けてプリント基板に実装する場合、吸着時の安 定性が向上するため、高い実装率を確保できるという効 果が得られる。また、保護膜21が耐熱性のあるアルミ ナ、シリカなどの酸化物からなる第1の保護層22と、 第1の保護層22の上面に形成された耐湿性のあるフェ ノール系あるいはエポキシ樹脂からなる第2の保護層2 3とで構成することによって、耐熱性、耐湿性に優れた 保護膜21で抵抗層14が覆われるため、抵抗層14が 熱や水分の影響を受けなくて済み、これにより、使用時 の抵抗値変化率を小さくできるという効果も得られる。 さらに、外部電極層16を上面電極層15の上面に設け ることによって、外部電極層20と上面電極層15との 接触面積が大きくなるため、熱衝撃などの環境負荷を受 けてもこの間の接触抵抗の増加を抑えることができ、こ れにより、抵抗層14が低抵抗値でも抵抗層14の抵抗 値に対する接触抵抗の増加分の割合を小さくできるた め、抵抗値変化率を低くできるという効果も得られる。 【0097】また、基板11の端面における各外部電極 層20間に位置する部分に凹部30が形成されたため、 この本発明の実施の形態2における抵抗器のような複数 の独立した抵抗層が1つのユニットになっている多連チ ップ抵抗器において、各抵抗層14に対応する各外部電 極層20間は凹部30によって(沿面距離ではなく)基

【0098】さらに、外部電極層20の上面を保護膜2 1の上面より上方に設けたため、基板11の上面側をプリント基板側に向けても外部電極20の上面がプリント 基板に接触するため、基板の上下面のどちらをプリント 基板側に向けても実装可能になるという効果も得られる。

板11の端面における距離が離れ、これにより、外部電

極層20の形成時に外部電極層20同士が接触して抵抗

層14同士が電気的に接続してしまうことを防止できる

という効果が得られる。

【0099】以上のように構成された本発明の実施の形態2における抵抗器について、以下にその製造方法を図面を参照しながら説明する。

【0100】図10~図16は、本発明の実施の形態2 における抵抗器の製造方法を示す図である。なお、各図 において、(b)は上面図、(a)は(b)のDーD線 断面図であり、これと同様に(d)(f)が上面図、

(c) (e) はそれぞれ(d) (f) のD-D線断面図である。

【0101】まず、図10(a)(b)に示すように、 樹脂、樹脂化合物、樹脂混合物などの樹脂系の材料から なる基板11を用意する(なお、この基板11は複数の 抵抗器を製造するために、1個の抵抗器より大きなシー ト状の基板をいう。1個の抵抗器を得るためにはこのシ ート状の基板を分割する必要がある。)。 【0102】次に、図10/ar(d)に示すように、基板11の上面にアウエナなどの配位物からなる下地層13を設ける。

【0105】次年、1014年)(1 に示す。)に、 抵抗暦14日日 11年により 夕により金系の料料から なる上面電位を100円円 11年に、 なお、必要に応じて基板 11年裏面に関する。 11年 15よい

【01に9)10月に、上に電極性にうおより抵抗層 1月をスパープに、円分子に後に、それぞれですトリ ソコスにも、デートには、一ンニンでするようにした ことにしって、「カード」でおより抵抗層1月を薄く 形成できる。アールーには28mmは積薄29で 悲想に、一分子には、「カード」であれてたりによりに、「は2mm」では、パアーンで成されてため、 抵抗は14mm」で、「大フーンででき、これに より、高空のが、「一」に、「大力できる」とい一分は一点。 とい一分は、音

【0109】次に、図ュニュ)(d) に示すように、 1個の抵抗器(110%、110%、110地拡抗器) 4を有すら部 分) 11111 ナストンニコントンニ面部円は1.5階の抵抗値 を割ったコントンコントンに、1 ーザートリミングに より。パミングで、4 ーコンる。

【 0 ~ 1 ~ 3 ~ ~ ~ 1 ~ ) ( \* ) に示けように、

少なくとも抵抗層14が露出するように、上面電極層15の一部の上面に第1のレジスト層25aをスクリーン印刷により設ける。この後第1のレジスト層25aが安定するように150℃、10分の温度で硬化する。

【0111】次に、図13(a)(b)に示すように、 露出した抵抗層14、上面電極層15の一部、第1のレ ジスト層25aの上面にスパッタによりアルミナなどの 酸化物からなる第1の保護層22を設ける。

【0112】次に、図13(c)(d)に示すように、 第1のレジスト層25aをリフトオフし、第1の保護層 22をパターンニングする。

【0113】このように、下地層13および保護膜21のうち少なくとも第1の保護層22をスパッタにより形成することによって、下地層13および保護膜21を緻密に形成できるため、抵抗層14へ湿気が入り込みにくくなり、これにより、抵抗層が安定するという効果が得られる。

【0114】次に、図13(e)(f)に示すように、第1の保護層22の上面に樹脂からなる第2の保護層23をスクリーン印刷により設ける。この後第2の保護層23が安定するように180℃、30分の温度で硬化する。このとき、第1の保護層22および第2の保護層23からなる保護膜21が、少なくとも全ての抵抗層14を覆うようにする。

【0115】このように、第2の保護層23をスクリーン印刷により設けることによって、第2の保護層23を 安価に形成できる。

【0116】次に、図14(a)(b)に示すように、 少なくとも保護膜21を覆うように第2のレジスト層3 1を設ける。

【0117】次に、図14(c)(d)に示すように、 紫外線硬化特性を有する接着剤が片面に設けられたシート固定材27を、基板11下面の全面に、接着剤が基板 11に接触するようにして貼り付けた後、分割用の縦溝 28を設ける。このとき、抵抗層14、上面電極層1 5、後述する端面電極層16が縦溝28に跨がるように する。

【0118】次に、図14(c)(T)に示すように、 基板11上面に露出している第2のレジスト層31、上面電極層15、縦溝28を覆うように、スパッタにより 端面電極層16を設ける。このとき、縦溝28内に端面電極層16が入り込む。

【0119】このように分割用の縦溝28に、端面電極層16をスパッタにより形成したことによって、非常に薄く端面電極層16を形成できるため、分割溝28内に確実に端面電極層16が入り込み、これにより、安定して端面電極層16を設けることができるという効果が得られる。

【0120】次に、図15(a)(b)に示すように、 第2のレジスト層31をリフトオフし、全ての保護膜2 1支工程扩展

【01221にイタート 見ず28. 横溝29は、ダイシンが正法で、エニーストー 「一を展射することによって記する。でお、エニーストー 「一を開射することによって記する。でお、エニーストーデーを用いれば、レーザーの照射された部分では、正大の高速に分割用の縦溝28と横溝2)を形式できてため、生工性が向上する。

横端 2011 しゃ 1 - 1 - 1 - 2 - 3 | 1 - 1 - 2 - 3 | 1 - 1 - 3 | 1 - 4 - 3 | 1 - 4 - 3 | 1 - 4 - 3 | 1 - 4 - 3 | 1 - 4 - 3 | 1 - 4 - 3 | 1 - 4 - 4 | 1 - 3 | 1 - 4 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 | 1 - 4 |

【① サー こう。ナー サー 12.6 一設け、ここ部分に 端面には同じては、切り欠き部(12.5 円)。3.0 とけで成されることに なる

【0.1.2.6.1 次に、1.11 (+) トーに示すように、 1 個点に トイエリート トロ無担性 Liを有する部 分)に ロッチ に コーニー ニュニー 含むように四部3 0 を、 トーニー コーニー コープラで、 1 間の抵抗 器 コーニー トローニー コーピア する部分)に 出当す る に コニュー ニーニー に てる。

**分離させて基板** 1 1 を分割するようにしたことによっ て、分割用の縦溝28と横溝29のうち一方を設けたと きに位置ずれを起こしてもう一方の分割用の溝を所定の 位置に設けることができなかったり、 悲板11を分割し た時に、個片状の各抵抗器がばらばらに散らばって、こ の後の工程が頻雑になることを防止できるという効果が 得られる。また、シート固定材27として紫外線硬化特 性を有する接着剤を含むものを用いたため、紫外線を照 射することによって高速でシート固定材27の接着力を 無くすことができ、これにより、生産性が向上すること に加え、シート固定材27の接着力を根本的に無くすこ とができるため、基板11から確実にシート固定材27 を分離できる。さらに、基板 1 1 からシート固定材 2 7 を分離させる工程は紫外線を照射することにより行うた め、紫外線を照射することによって容易にシート固定材 27の接着力を無くすことができ、これにより、容易に 基板11からシート固定材27を分離できる。

【0130】最後に、図16(c)(d)に示すように、端面電極層16の表面および露出している上面電極層15の上面に、ニッケルめっき層18と低融点金属めっき層19からなるめっき層17を設ける。

【0131】このとき、保護膜21の上面より各外部電極層20の上面が上方になるようにする。

【0132】図17は、本発明の実施の形態2における 抵抗器をプリント基板32に、基板11の上面側をプリ ント基板32に向けて実装したものを示す断面図であ る。

【0133】通常は基板の下面側をプリント基板側に向けて外部電極をプリント基板と接触させて実装するが、図17から明らかなように、基板11の上面側をプリント基板側に向けても外部電極20の上面が実装用のはんだ33を介してプリント基板32に接触するため、基板の上下面のどちらをプリント基板側に向けても実装可能になる。なお、このような効果は、1個の独立した抵抗層を有する抵抗器や、複数の独立した抵抗層が1つのユニットになっている多連チップ抵抗器のいずれにもいえる。

【0134】上記した本発明の実施の形態2における抵抗器は、アルミナより柔らかい樹脂系の材料からなる基板11を用いたため、基板切断用の刃の摩耗を抑えることができ、これにより、基板の切断コストを抑えることができるという効果が得られる。

【0135】また、上面電極層15、抵抗層14、端面電極層16、保護膜21などの形成後に基板11を分割するため、基板11を寸法ランクに分類する必要が無くなり、これにより、工程の煩雑さが解消するという効果も得られる。

【0136】さらに、上面電極層15、抵抗層14、端面電極層16、保護膜21などの形成後に基板11を分割するため、端面電極層16などを形成するために基板

1 1 を一切。円円(12) 別でる定要は作く、これにより、 一回がたけれる。ローター「居民の」、問題を得ることが でき、でするよう。 コロットに変化するこという対点も得 られる

### [ ( 1 2 6

【操作》为"生物"。

(L. L. Company Company)、サルコにははいる抵抗器の 金質

【図』では、「大法を集べ図」

【ELET / A HARRIEN でも方法を示す図

【図6】(ま)。」 「同門科問の。」は写法を示す図

余二

【日本なり、コンペード、日本地震の場合性を示す図

【物では、これでは、これでは、関係では遺力法を含す図

【八十二年】

【図101111 日常には、「温度が法を示す図

【図15】(6)(6) 日) 「人口以下語で法を示す図

【、「アプンスとは、シャイン また、これでは、「Manager」 プロスは、は、アクトランストではは関す

[1] 8] ( ) ( ) ( ) ( ) ( ) ( ) ( )

(同野学) 出海下区

【17 9】 おここのも見りは、過ぎが決を示す図

【 : の に

1 基本

11 切1

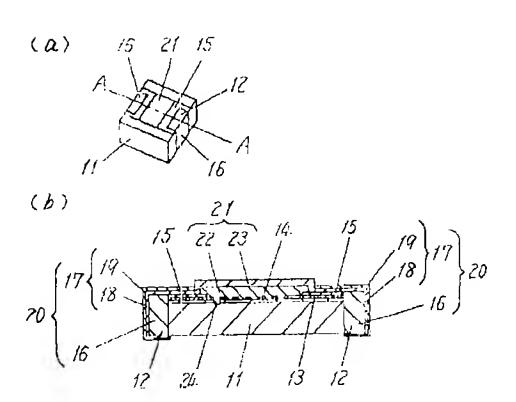
11 下心。

- 15 上面電極層
- 16 端面電極層
- 17 めっき層
- 20 外部電極層
- 21 保護膜
- 22 第1の保護層

- 23 第20限置日
- 26 3000
- 27 34 47.77
- 28 1111
- 20 横滑
- 3 " 四部"

### 【図1】

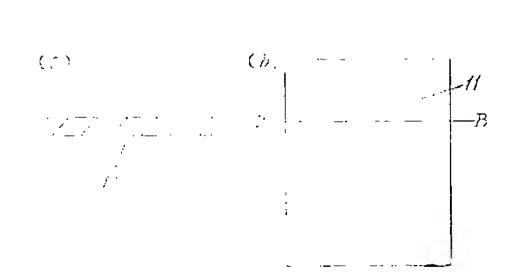
- 月葵 极
- 12 切り欠き郡
- 13 下地層
- 4 抵抗層
- 15 上面電極層
- 16 端面電極層
- 17 めっき層
- 20 外部電極層
- 21 保護膜
- 22 第10保護會
- 23 第2の保護層

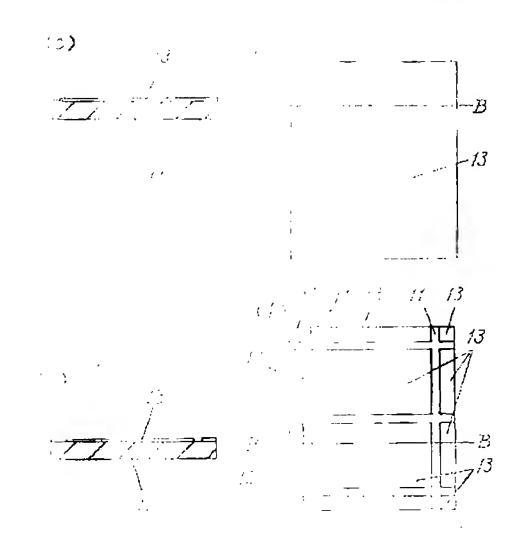


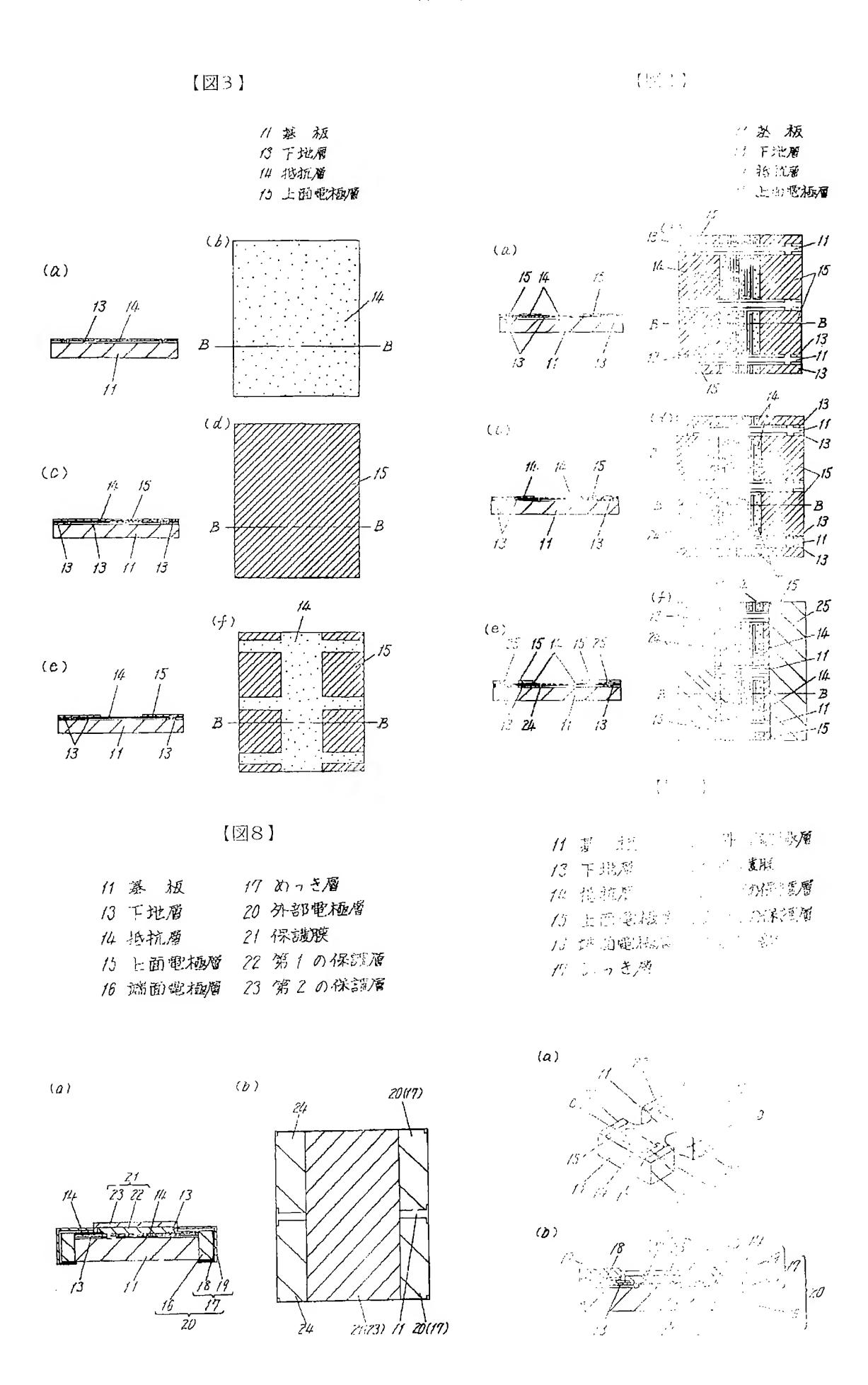
#### 11.1

化置 海

少可數學

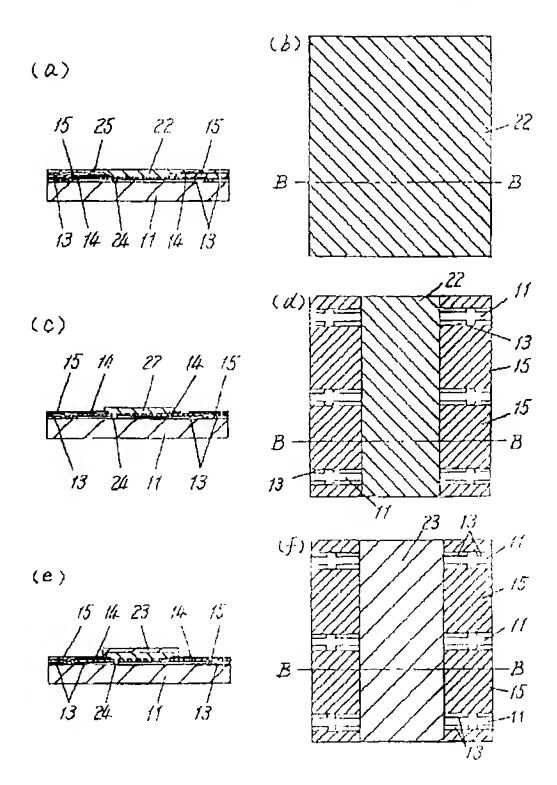




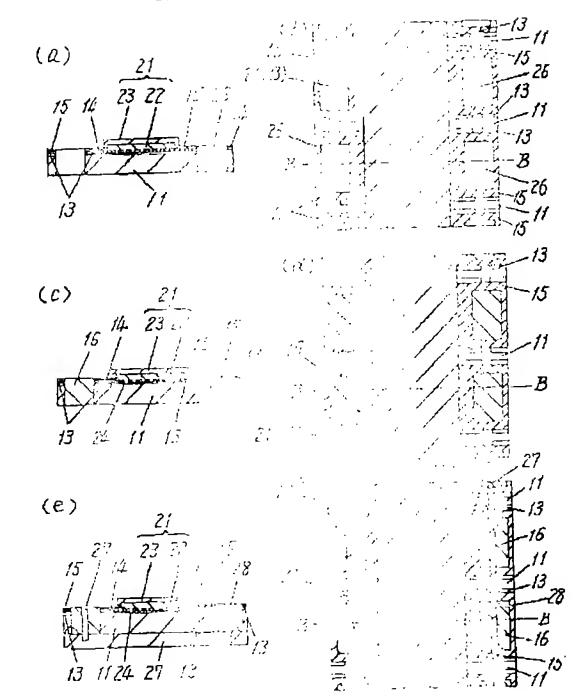


### 【図5】

11 基 板 15 上面電極層 13 下地層 22 第1の保護層 14 指抗層 23 第2の保護層



### 



### 【図17】

11 基 极

13 下地图

14 抢抗層

15 上面電極層

16 端面电标图

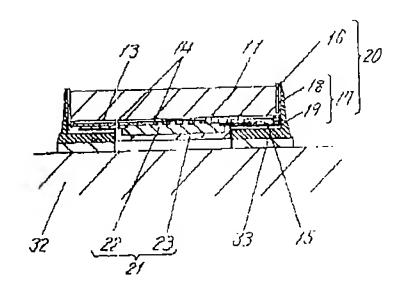
17 おっき層

20 外部电極層

21 保護機

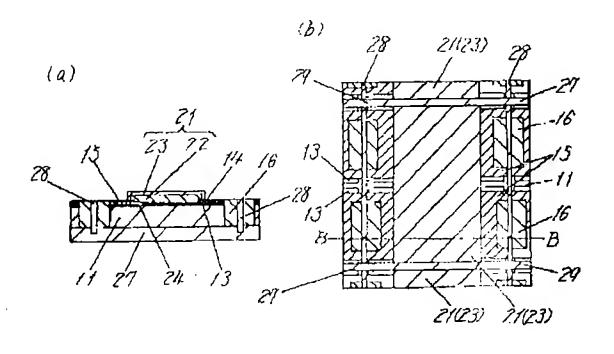
22 第10個額

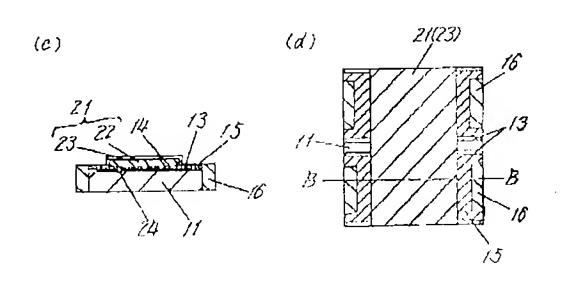
23 第2の保護層



### 【図7】

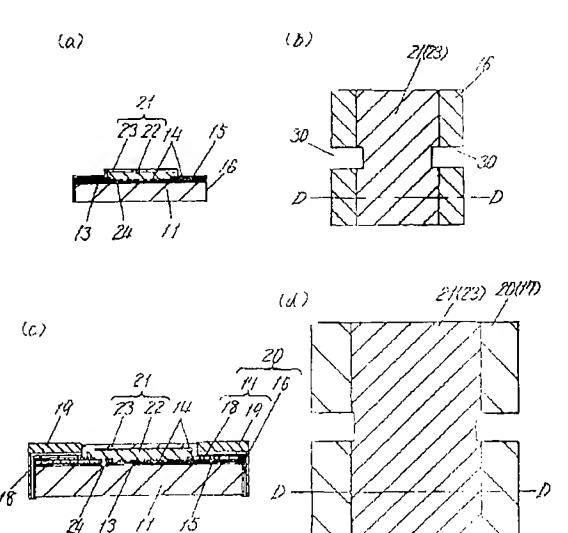
- 11 差 板 22 第 1 の 保護層 13 下地層 23 第 2 の 保護層 14 抵抗層 27 シート 固定材
- 15 上面電極層 28 縱 溝 21 保護膜 29 凝 溝



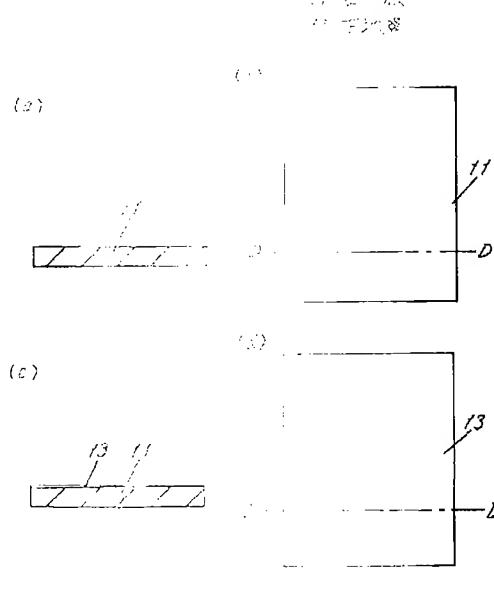


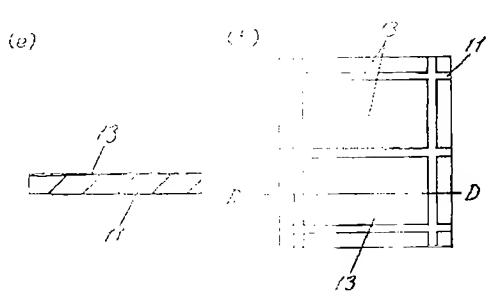
【図16】

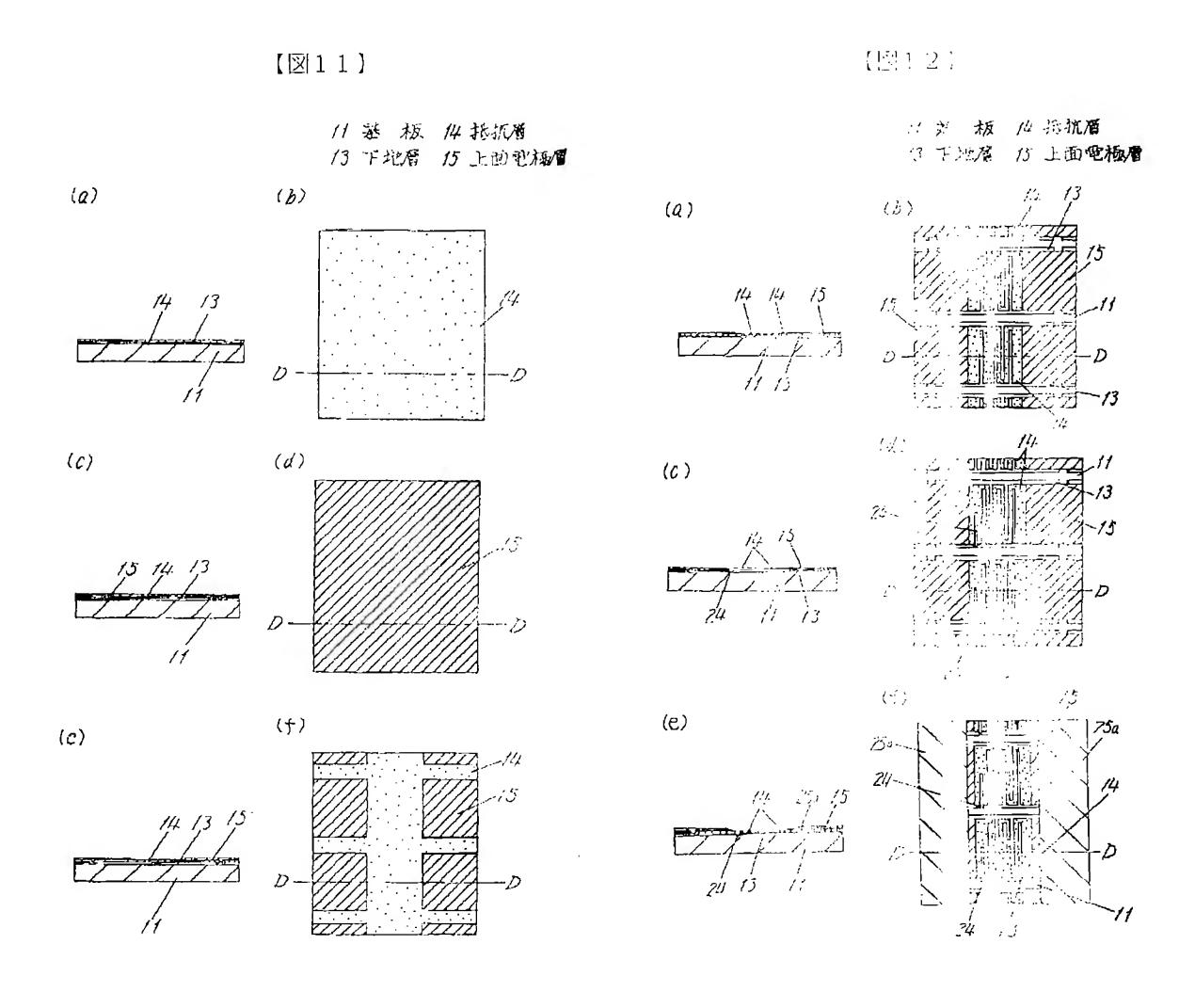
11 基 板 17 めっき暦 13 下地層 20 外部電極層 14 抵抗層 21 保護膜 15 上面電極層 22 第 1 の保護層 16 端面電極層 23 第 2 の保護層

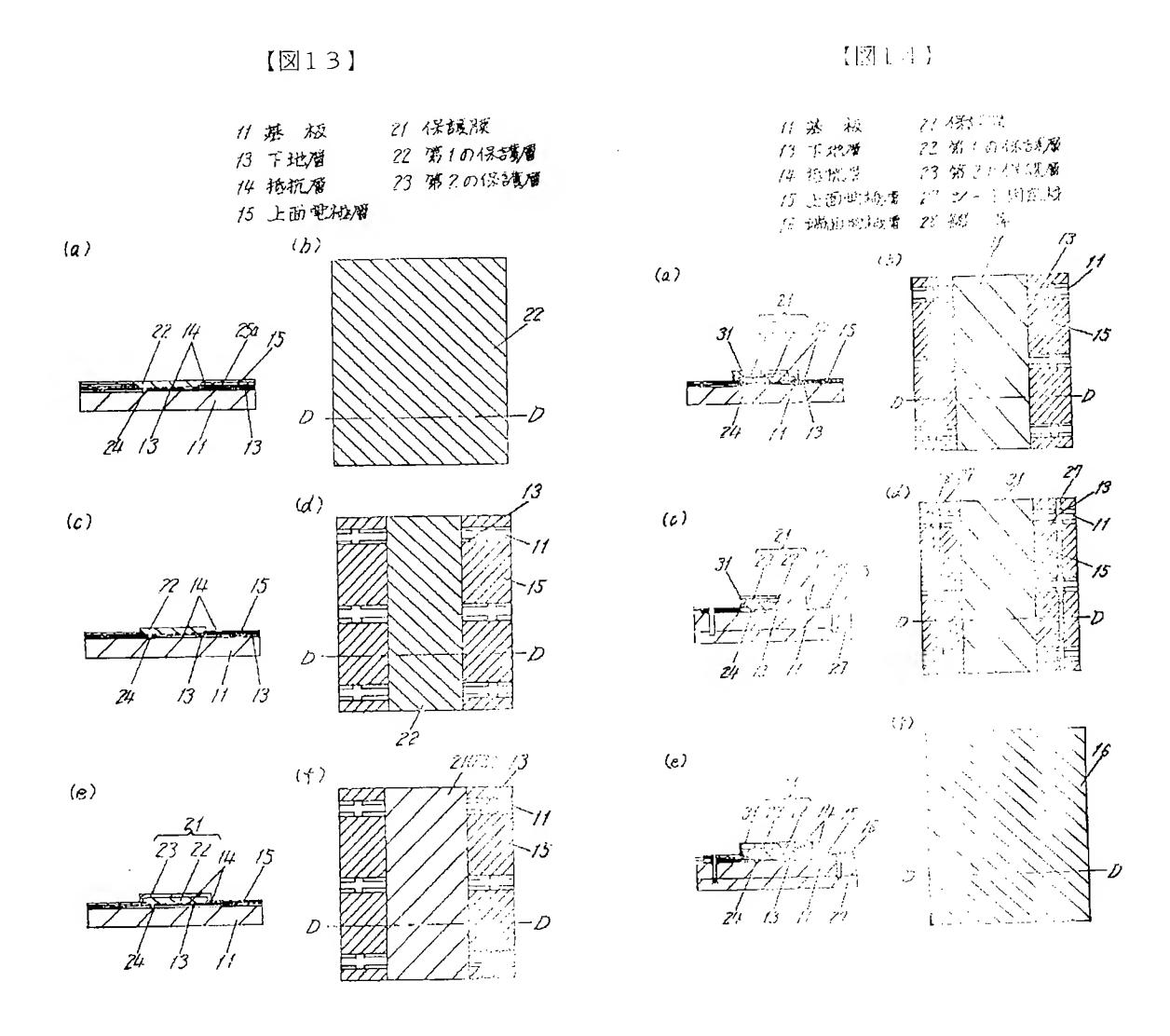


### [[图]] (1]

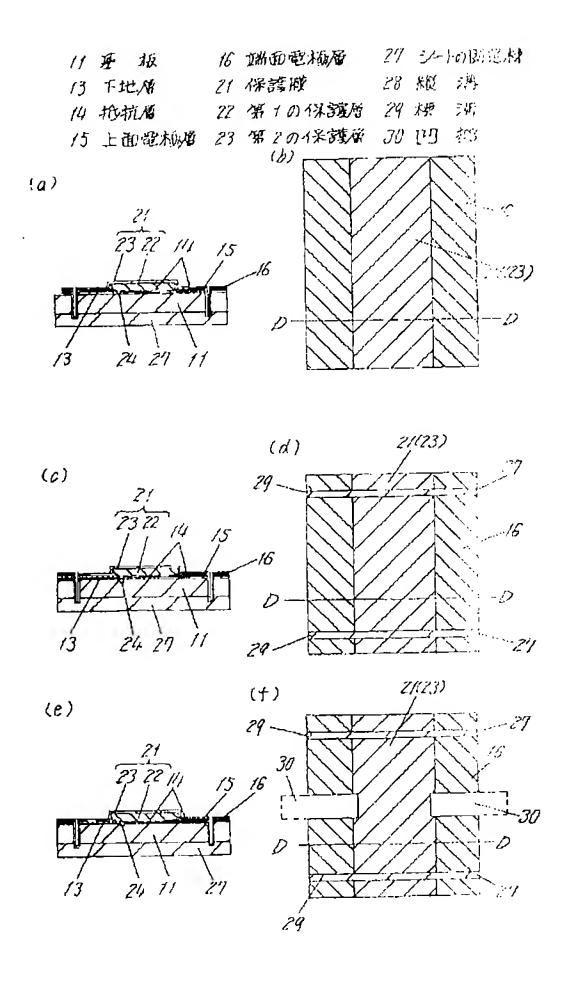




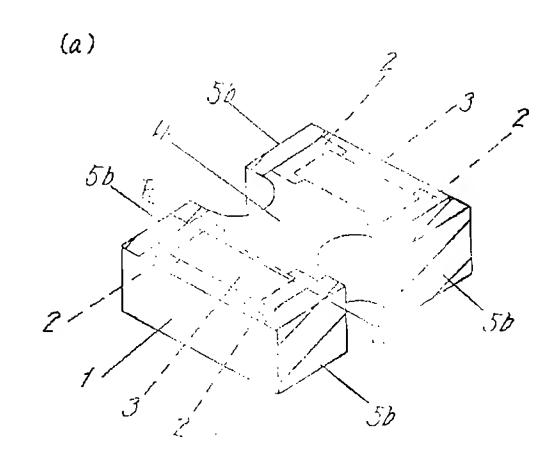


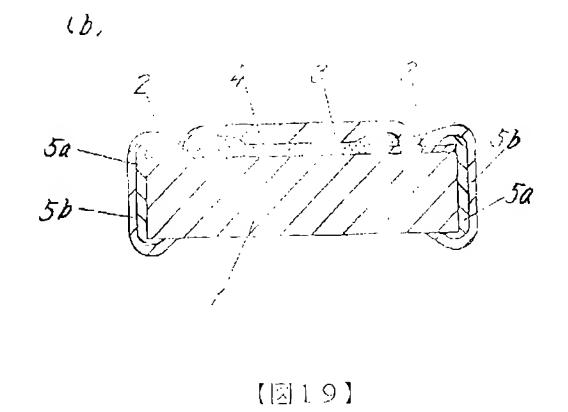


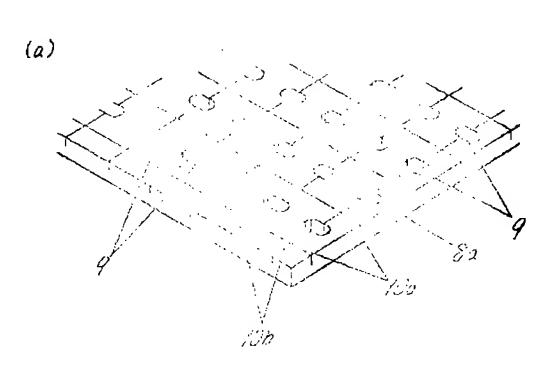
【図15】

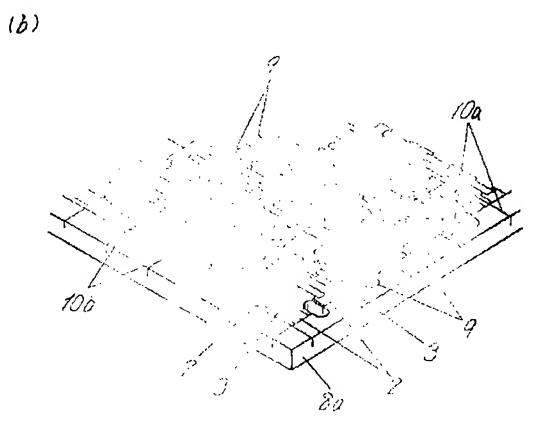


## [[]18]

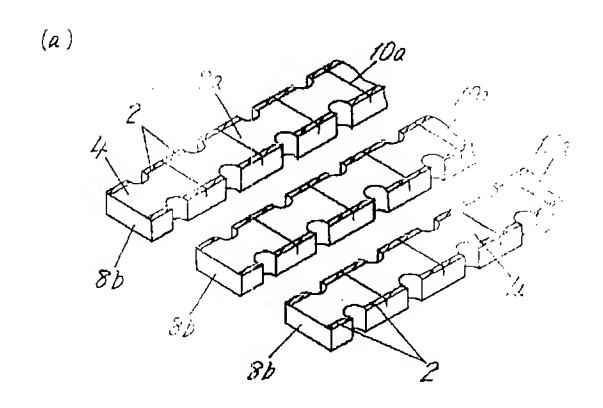




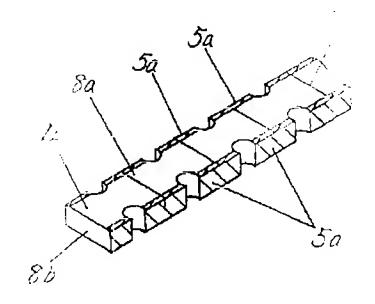




# 【図20】



(6)



## フロントページの続き

Fターム(参考) 5E032 BA11 BB13 CA02 CC03 LC07 CC14 CC16 CC18 TA11 TD02 5E033 AA01 BB02 BC08 BE02 PL04 BF05 BG02 BH02 BH03